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TEXAS INSTRUMENTS

OPA316, OPA2316, OPA2316S, OPA4316

SBOS703F – APRIL 2014 – REVISED OCTOBER 2016

OPAx316 10-MHz, Low-Power, Low-Noise, RRIO, 1.8-V CMOS Operational Amplifier

1 Features

- Unity-Gain Bandwidth: 10 MHz
- Low I_Q: 400 µA/ch
- Wide Supply Range: 1.8 V to 5.5 V
- Low Noise: 11 nV/$\sqrt{\text{Hz}}$ at 1 kHz
- Low Input Bias Current: ±5 pA
- Offset Voltage: ±0.5 mV
- Unity-Gain Stable
- Internal RFI-EMI Filter
- Shutdown Version: OPA2316S
- Extended Temperature Range: –40°C to +125°C

2 Applications

- Battery-Powered Instruments:
  - Consumer, Industrial, Medical
  - Notebooks, Portable Media Players
- Sensor Signal Conditioning
- Automotive Applications
- Barcode Scanners
- Active Filters
- Audio

3 Description

The OPAx316 family of single, dual, and quad operational amplifiers represents a new generation of general-purpose, low-power operational amplifiers. Featuring rail-to-rail input and output swings, low quiescent current (400 µA/ch typical) combined with a wide bandwidth of 10 MHz and very-low noise (11 nV/$\sqrt{\text{Hz}}$ at 1 kHz) makes this family attractive for a variety of applications that require a good balance between cost and performance. The low input bias current supports those operational amplifiers to be used in applications with MΩ source impedances.

The robust design of the OPAx316 provide ease-of-use to the circuit designer—a unity-gain stable, integrated RFI-EMI rejection filter, no phase reversal in overdrive condition, and high electrostatic discharge (ESD) protection (4-kV HBM).
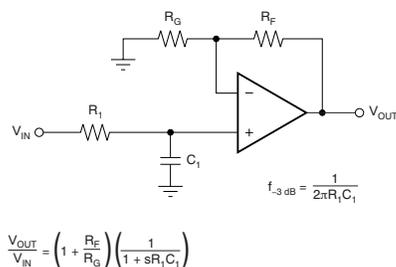
These devices are optimized for low-voltage operation as low as 1.8 V (±0.9 V) and up to 5.5 V (±2.75 V). This latest addition of low-voltage CMOS operational amplifiers, in conjunction with the OPAx313 and OPAx314 provide a family of bandwidth, noise, and power options to meet the needs of a wide variety of applications.

Device Information[1]

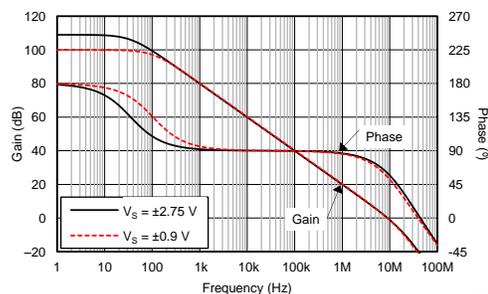| PART NUMBER	PACKAGE	BODY SIZE (NOM)
OPA316	SC-70 (5)	1.25 mm × 2.00 mm
	SOT-23 (5)	1.60 mm × 2.90 mm
OPA2316	DFN (8)	3.00 mm × 3.00 mm
	MSOP, VSSOP (8)	3.00 mm × 3.00 mm
	SOIC (8)	3.91 mm × 4.90 mm
OPA2316S	MSOP, VSSOP (10)	3.00 mm × 3.00 mm
	X2QFN (10)	1.50 mm × 2.00 mm
OPA4316	TSSOP (14)	4.40 mm × 5.00 mm
	SOIC (14)	8.65 mm × 3.91 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Single-Pole, Low-Pass Filter

$$f_{-3\,dB} = \frac{1}{2\pi R_1 C_1}$$

$$\frac{V_{OUT}}{V_{IN}} = \left(1 + \frac{R_F}{R_G}\right)\left(\frac{1}{1 + sR_1C_1}\right)$$

Low-Supply Current (400 µA/ch) for 10-MHz Bandwidth

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

Table of Contents

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision E (May 2016) to Revision F	**Page**
• Added SOIC (14) / OPA4316 body size information to *Device Information* table	1
• Added D package to PW package pinout drawing	4
• Added D (SOIC) thermal information to *Thermal Information*: OPA4316 table	8

Changes from Revision D (December 2014) to Revision E	**Page**
• Added new "*RUG*" package	1

Changes from Revision C (October 2014) to Revision D	**Page**
• Added *Shutdown* section to Electrical Characteristics table	10
• Added *Related Documentation* section	27

Changes from Revision B (August 2014) to Revision C	**Page**
• Updated devices and packages in *Device Information* table	1
• Added thermal information for OPA2316S and OPA4316	7

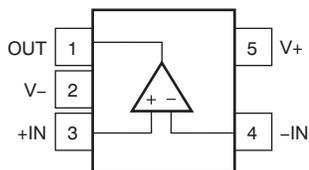| **Changes from Revision A (April 2014) to Revision B**	**Page**
• Added OPA2316 to the *Device Information* table	1
• Added thermal information for OPA2316	7
• Added channel separation to *Electrical Characteristics*	9
• Added GBP instead of UGB in the *Electrical Characteristics*	9
• Added Channel Separation vs Frequency plot	16

Changes from Original (April 2014) to Revision A   **Page**

5 Pin Configuration and Functions

DCK Package
5-Pin SC70
Top View

```
+IN   1          5   V+
V–    2          
–IN   3          4   OUT
```
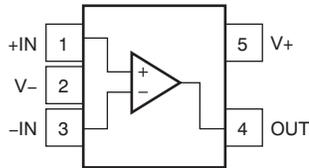
DBV Package
5-Pin SOT-23
Top View

```
OUT   1          5   V+
V–    2          
+IN   3          4   –IN
```

DRG Package
8-Pin DFN
Top View

```
OUT A   1    Exposed      8   V+
–IN A   2    Thermal      7   OUT B
+IN A   3    Die Pad      6   –IN B
             on
V–      4    Underside(2) 5   +IN B
```
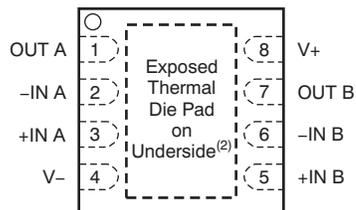
Pitch: 0.5 mm.

Connect thermal pad to V–. Pad size: 2.00 mm × 1.20 mm.

D, DGK Packages
8-Pin MSOP, SO
Top View

```
OUT A   1          8   V+
–IN A   2          7   OUT B
+IN A   3          6   –IN B
V–      4          5   +IN B
```
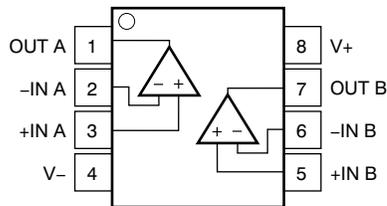
DGS Package
10-Pin MSOP
Top View

```
OUT A    1          10   V+
–IN A    2           9   OUT B
+IN A    3           8   –IN B
V–       4           7   +IN B
SHDN A   5           6   SHDN B
```
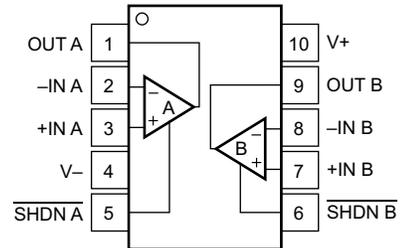
RUG Package
10-Pin QFN
Top View

```
               +IN A
                 10
V–      1              9    –IN A
SHDN A  2              8    OUT A
SHDN B  3              7    V+
+IN B   4              6    OUT B
                 5
               –IN B
```
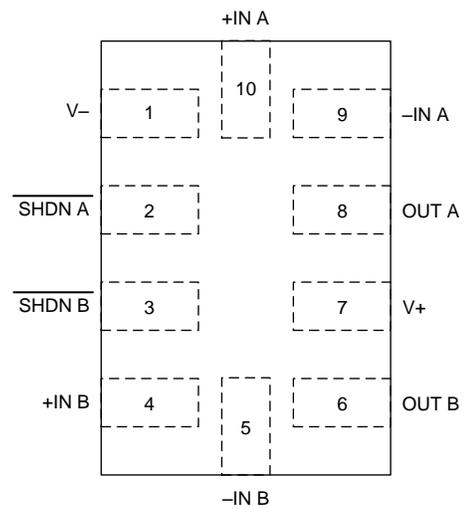
D, PW Packages
14-Pin SOIC, TSSOP
Top View

```
OUT A   1    A    D    14   OUT D
–IN A   2              13   –IN D
+IN A   3              12   +IN D
V+      4              11   V–
+IN B   5              10   +IN C
–IN B   6    B    C     9   –IN C
OUT B   7               8   OUT C
```
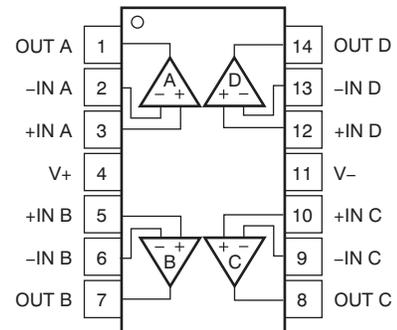
Pin Functions

NAME	PIN							DESCRIPTION
	OPA316		OPA2316	OPA2316S		OPA4316		
	DBV	DCK	D, DGK, DRG	DGS	RUG	PW	D	
+IN	3	1	—	—	—	—	—	Noninverting input
+IN A	—	—	3	3	10	3	3	Noninverting input
+IN B	—	—	5	7	4	5	5	Noninverting input
+IN C	—	—	—	—	—	10	10	Noninverting input
+IN D	—	—	—	—	—	12	12	Noninverting input
–IN	4	3	—	—	—	—	—	Inverting input
–IN A	—	—	2	2	9	2	2	Inverting input
–IN B	—	—	6	8	5	6	6	Inverting input
–IN C	—	—	—	—	—	9	9	Inverting input
–IN D	—	—	—	—	—	13	13	Inverting input
OUT	1	4	—	—	—	—	—	Output
OUT A	—	—	1	1	8	1	1	Output
OUT B	—	—	7	9	6	7	7	Output
OUT C	—	—	—	—	—	8	8	Output
OUT D	—	—	—	—	—	14	14	Output
SHDN A	—	—	—	5	2	—	—	Shutdown (logic low), enable (logic high)
SHDN B	—	—	—	6	3	—	—	Shutdown (logic low), enable (logic high)
V+	5	5	8	10	7	4	4	Positive supply
V–	2	2	4	4	1	11	11	Negative supply or ground (for single-supply operation)

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Product Folder Links: *OPA316 OPA2316 OPA2316S OPA4316*

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature (unless otherwise noted) [1]

			MIN	MAX	UNIT
Supply voltage				7	V
Signal input pins	Voltage [2]	Common-mode	(V−) − 0.5	(V+) + 0.5	V
		Differential		(V+) − (V−) + 0.2	V
	Current [2]		−10	10	mA
Output short-circuit [3]				Continuous	
T_A	Operating temperature		−55	150	°C
T_J	Junction temperature			150	°C
T_{stg}	Storage temperature		−65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) Input pins are diode-clamped to the power-supply rails. Current limit input signals that can swing more than 0.5 V beyond the supply rails to 10 mA or less.
(3) Short-circuit to ground, one amplifier per package.

6.2 ESD Ratings

over operating free-air temperature range (unless otherwise noted).

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 [1]	±4000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101 [2]	±1500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted).

		MIN	MAX	UNIT
V_S	Supply voltage	1.8	5.5	V
	Specified temperature	−40	125	°C

6.4 Thermal Information: OPA316

	THERMAL METRIC [1]	OPA316		UNIT
		DBV (SOT23)	DCK (SC70)	
		5 PINS	5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance [2]	221.7	263.3	°C/W
$R_{\theta JC(top)}$	Junction-to-case(top) thermal resistance [3]	144.7	75.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance [4]	49.7	51	°C/W
ψ_{JT}	Junction-to-top characterization parameter [5]	26.1	1	°C/W
ψ_{JB}	Junction-to-board characterization parameter [6]	49	50.3	°C/W

(1) For more information about traditional and new thermal metrics, see *Semiconductor and IC Package Thermal Metrics* (SPRA953).
(2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
(3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
(4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
(5) The junction-to-top characterization parameter, ψ_{JT}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining $R_{\theta JA}$, using a procedure described in JESD51-2a (sections 6 and 7).
(6) The junction-to-board characterization parameter, ψ_{JB}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining $R_{\theta JA}$, using a procedure described in JESD51-2a (sections 6 and 7).

Product Folder Links: *OPA316 OPA2316 OPA2316S OPA4316*

Thermal Information: OPA316 (continued)

THERMAL METRIC[1]		OPA316		UNIT
		DBV (SOT23)	DCK (SC70)	
		5 PINS	5 PINS	
$R_{\theta JC(bot)}$	Junction-to-case(bottom) thermal resistance[7]	N/A	N/A	°C/W

(7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

6.5 Thermal Information: OPA2316

THERMAL METRIC[1]		OPA2316			UNIT
		D (SO)	DGK (MSOP)	DRG (DFN)	
		8 PINS	8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance[2]	127.2	186.6	56.3	°C/W
$R_{\theta JC(top)}$	Junction-to-case(top) thermal resistance[3]	71.6	78.8	72.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance[4]	68.2	107.9	31	°C/W
ψ_{JT}	Junction-to-top characterization parameter[5]	22	15.5	2.3	°C/W
ψ_{JB}	Junction-to-board characterization parameter[6]	67.6	106.3	21.2	°C/W
$R_{\theta JC(bot)}$	Junction-to-case(bottom) thermal resistance[7]	N/A	N/A	10.9	°C/W

(1) For more information about traditional and new thermal metrics, see *Semiconductor and IC Package Thermal Metrics* (SPRA953).
(2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
(3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
(4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
(5) The junction-to-top characterization parameter, ψ_{JT}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining $R_{\theta JA}$, using a procedure described in JESD51-2a (sections 6 and 7).
(6) The junction-to-board characterization parameter, ψ_{JB}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining $R_{\theta JA}$, using a procedure described in JESD51-2a (sections 6 and 7).
(7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

6.6 Thermal Information: OPA2316S

THERMAL METRIC[1]		OPA2316S		UNIT
		DGS (MSOP)	QFN (RUG)	
		10 PINS	10 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance[2]	189.6	158	°C/W
$R_{\theta JC(top)}$	Junction-to-case(top) thermal resistance[3]	73.9	52	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance[4]	110.7	88	°C/W
ψ_{JT}	Junction-to-top characterization parameter[5]	13.4	1	°C/W
ψ_{JB}	Junction-to-board characterization parameter[6]	109.1	87	°C/W
$R_{\theta JC(bot)}$	Junction-to-case(bottom) thermal resistance[7]	N/A	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see *Semiconductor and IC Package Thermal Metrics* (SPRA953).
(2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
(3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
(4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
(5) The junction-to-top characterization parameter, ψ_{JT}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining $R_{\theta JA}$, using a procedure described in JESD51-2a (sections 6 and 7).
(6) The junction-to-board characterization parameter, ψ_{JB}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining $R_{\theta JA}$, using a procedure described in JESD51-2a (sections 6 and 7).
(7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

6.7   Thermal Information: OPA4316

THERMAL METRIC[1]		OPA4316		UNIT
		PW (TSSOP)	D (SOIC)	
		14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance[2]	117.2	87.0	°C/W
$R_{\theta JC(top)}$	Junction-to-case(top) thermal resistance[3]	46.2	44.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance[4]	58.9	41.7	°C/W
ψ_{JT}	Junction-to-top characterization parameter[5]	4.9	11.6	°C/W
ψ_{JB}	Junction-to-board characterization parameter[6]	58.3	41.4	°C/W
$R_{\theta JC(bot)}$	Junction-to-case(bottom) thermal resistance[7]	N/A	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see *Semiconductor and IC Package Thermal Metrics* (SPRA953).
(2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
(3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
(4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
(5) The junction-to-top characterization parameter, ψ_{JT}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining $R_{\theta JA}$, using a procedure described in JESD51-2a (sections 6 and 7).
(6) The junction-to-board characterization parameter, ψ_{JB}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining $R_{\theta JA}$, using a procedure described in JESD51-2a (sections 6 and 7).
(7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

Product Folder Links: *OPA316 OPA2316 OPA2316S OPA4316*

6.8 Electrical Characteristics

V_S (total supply voltage) = (V+) − (V−) = 1.8 V to 5.5 V.
at T_A = 25°C, R_L = 10 kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2, unless otherwise noted.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFFSET VOLTAGE						
V_{OS}	Input offset voltage	V_S = 5 V		±0.5	±2.5	mV
		V_S = 5 V, T_A = −40°C to 125°C			±3.5	mV
dV_{OS}/dT	Drift	V_S = 5 V, T_A = −40°C to 125°C		±2	±10	μV/°C
PSRR	vs power supply	V_S = 1.8 V – 5.5 V, V_{CM} = (V−)		±30	±150	μV/V
		V_S = 1.8 V – 5.5 V, V_{CM} = (V−), T_A = −40°C to 125°C			±250	μV/V
	Channel separation, dc	At dc		10		μV/V
INPUT VOLTAGE RANGE						
V_{CM}	Common-mode voltage	V_S = 1.8 V to 2.5 V	(V−) − 0.2		(V+)	V
		V_S = 2.5 V to 5.5 V	(V−) − 0.2		(V+) + 0.2	V
CMRR	Common-mode rejection ratio	V_S = 1.8 V, (V−) − 0.2 V < V_{CM} < (V+) − 1.4 V, T_A= −40°C to 125°C	70	86		dB
		V_S = 5.5 V, (V−) − 0.2 V < V_{CM} < (V+) − 1.4 V, T_A= −40°C to 125°C	76	90		dB
		V_S = 1.8 V, V_{CM} = −0.2 V to 1.8 V, T_A= −40°C to 125°C	57	72		dB
		V_S = 5.5 V, V_{CM} = −0.2 V to 5.7 V, T_A= −40°C to 125°C	65	80		dB
INPUT BIAS CURRENT						
I_B	Input bias current			±5	±15	pA
		T_A= −40°C to 125°C			±15	nA
I_{OS}	Input offset current			±2	±15	pA
		T_A= −40°C to 125°C			±8	nA
NOISE						
E_n	Input voltage noise (peak-to-peak)	V_S = 5 V, f = 0.1 Hz to 10 Hz		3		μV$_{PP}$
e_n	Input voltage noise density	V_S = 5 V, f = 1 kHz		11		nV/√Hz
i_n	Input current noise density	f = 1 kHz		1.3		fA/√Hz
INPUT IMPEDANCE						
Z_{ID}	Differential			2 ‖ 2		10^{16}Ω ‖ pF
Z_{IC}	Common-mode			2 ‖ 4		10^{11}Ω ‖ pF
OPEN-LOOP GAIN						
A_{OL}	Open-loop voltage gain	V_S = 1.8 V, (V−) + 0.04 V < V_O < (V+) − 0.04 V, R_L = 10 kΩ	94	100		dB
		V_S = 5.5 V, (V−) + 0.05 V < V_O < (V+) − 0.05 V, R_L = 10 kΩ	104	110		dB
		V_S = 1.8 V, (V−) + 0.1 V < V_O < (V+) − 0.1 V, R_L = 2 kΩ	90	96		dB
		V_S = 5.5 V, (V−) + 0.15 V < V_O < (V+) − 0.15 V, R_L = 2 kΩ	100	106		dB
		V_S = 5.5 V, (V−) + 0.05 V < V_O < (V+) − 0.05 V, R_L = 10 kΩ, T_A= −40°C to 125°C	86			dB
		V_S = 5.5 V, (V−) + 0.15 V < V_O < (V+) − 0.15 V, R_L = 2 kΩ, T_A= −40°C to 125°C	84			dB
FREQUENCY RESPONSE						
GBP	Gain bandwidth product	V_S = 5 V, G = +1		10		MHz
$φ_m$	Phase margin	V_S = 5 V, G = +1		60		Degrees
SR	Slew rate	V_S = 5 V, G = +1		6		V/μs
t_S	Settling time	To 0.1%, V_S = 5 V, 2-V step , G = +1, C_L = 100 pF		1		μs
		To 0.01%, V_S = 5 V, 2-V step , G = +1, C_L = 100 pF		1.66		μs
t_{OR}	Overload recovery time	V_S = 5 V, V_{IN} × gain = V_S		0.3		μs
THD + N	Total harmonic distortion + noise[1]	V_S = 5 V, V_O = 0.5 V$_{RMS}$, G = +1, f = 1 kHz		0.0008%		

(1)   Third-order filter; bandwidth = 80 kHz at −3 dB.

Electrical Characteristics (continued)

V_S (total supply voltage) = (V+) − (V−) = 1.8 V to 5.5 V.

at T_A = 25°C, R_L = 10 kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
OUTPUT						
V_O	Voltage output swing from supply rails	V_S = 1.8 V, R_L = 10 kΩ, T_A= −40°C to 125°C			15	mV
		V_S = 5.5 V, R_L = 10 kΩ, T_A= −40°C to 125°C			30	mV
		V_S = 1.8 V, R_L = 2 kΩ, T_A= −40°C to 125°C			60	mV
		V_S = 5.5 V, R_L = 2 kΩ, T_A= −40°C to 125°C			120	mV
I_{SC}	Short-circuit current	V_S = 5 V		±50		mA
Z_O	Open-loop output impedance	V_S = 5 V, f = 10 MHz		250		Ω
POWER SUPPLY						
V_S	Specified voltage		1.8		5.5	V
I_Q	Quiescent current per amplifier	V_S = 5 V, I_O = 0 mA, T_A= −40°C to 125°C		400	500	µA
	Power-on time	V_S = 0 V to 5.5 V		200		µs
SHUTDOWN (V_S = 1.8 V to 5.5 V)[2]						
I_{QSD}	Quiescent current, per device	All amplifiers disabled, $\overline{SHDN}$ = V_{S-}		0.01	1	µA
		One amplifier disabled (OPA2316S)		345		µA
V_{IH}	High voltage (enabled)	Amplifier enabled	(V+) − 0.5			V
V_{IL}	Low voltage (disabled)	Amplifier disabled			(V−) + 0.2	V
t_{ON}	Amplifier enable time[3]	Full shutdown, G = 1, V_{OUT} = 0.9 × V_S / 2[4]		13		µs
		Partial shutdown, G = 1, V_{OUT} = 0.9 × V_S / 2[4]		10		µs
t_{OFF}	Amplifier disable time[3]	G = 1, V_{OUT} = 0.1 × V_S / 2		5		µs
	$\overline{SHDN}$ pin input bias current (per pin)	V_{IH} = 5 V		3.5		pA
		V_{IL} = 0 V		2.5		pA
TEMPERATURE						
	Specified temperature		−40		125	°C
T_A	Operating temperature		−55		150	°C
T_{stg}	Storage temperature		−65		150	°C

(2) Ensured by design and characterization; not production tested.
(3) Enable time (t_{ON}) and disable time (t_{OFF}) are defined as the time interval between the 50% point of the signal applied to the $\overline{SHDN}$ pin and the point at which the output voltage reaches the 10% (disable) or 90% (enable) level.
(4) Full shutdown refers to the dual OPA2316S having both channels A and B disabled ($\overline{SHDN\_A}$ = $\overline{SHDN\_B}$ = V_{S-}). For partial shutdown, only one $\overline{SHDN}$ pin is exercised; in partial mode, the internal biasing and oscillator remain operational and the enable time is shorter.

6.9 Typical Characteristics

at T_A = 25°C, V_S = 5.5 V, R_L = 10 kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2, unless otherwise noted.

Distribution taken from 12551 amplifiers
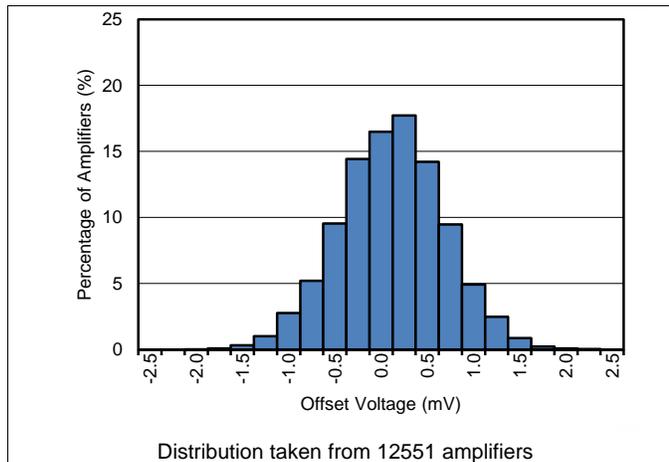
Figure 1. Offset Voltage Production Distribution

T_A = −40°C to +125°C, Distribution taken from 70 amplifiers
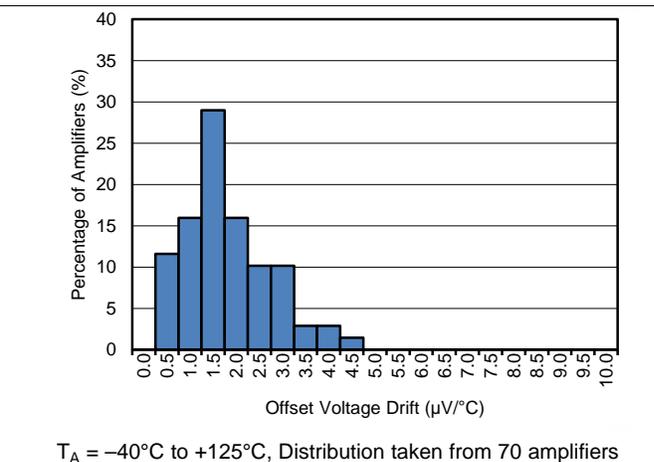
Figure 2. Offset Voltage Drift Distribution

9 typical units shown
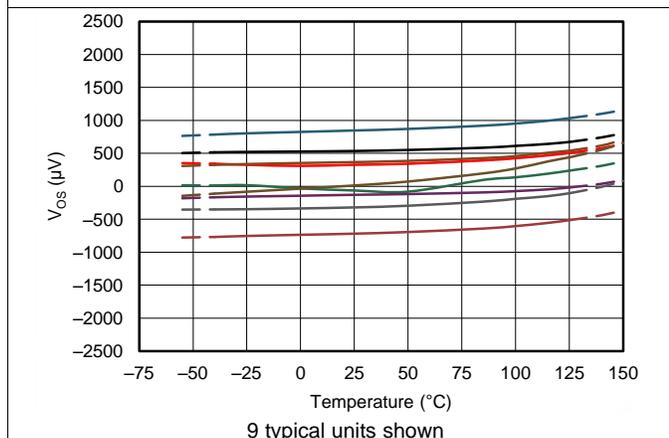
Figure 3. Offset Voltage vs Temperature

V+ = 2.75 V, V− = −2.75 V, 9 typical units shown
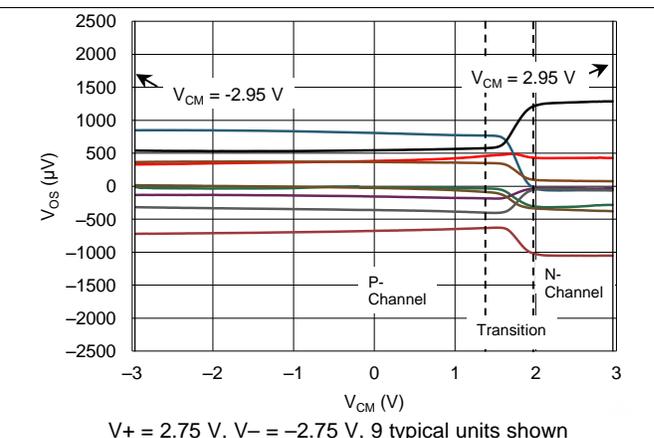
Figure 4. Offset Voltage vs Common-Mode Voltage

V+ = 0.9 V to 2.75 V, V− = −0.9 V to −2.75 V,
9 typical units shown
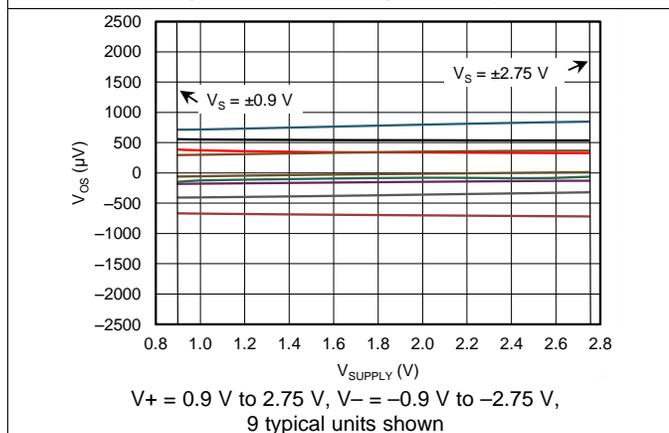
Figure 5. Offset Voltage vs Power Supply

V_{CM} < (V+) − 1.4 V
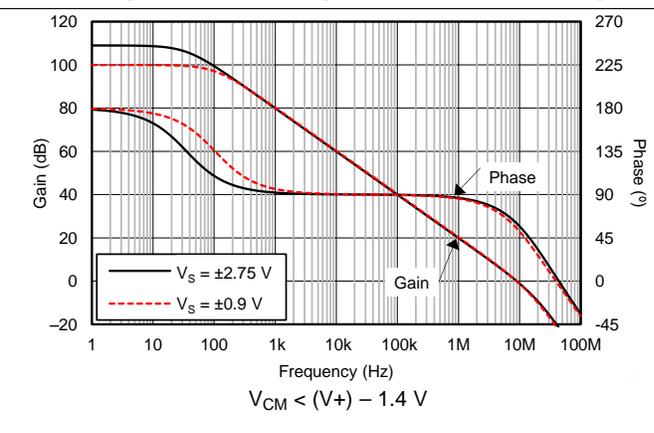
Figure 6. Open-Loop Gain and Phase vs Frequency

Product Folder Links: *OPA316 OPA2316 OPA2316S OPA4316*

Typical Characteristics (continued)

at $T_A = 25°C$, $V_S = 5.5$ V, $R_L = 10$ kΩ connected to $V_S / 2$, $V_{CM} = V_S / 2$, and $V_{OUT} = V_S / 2$, unless otherwise noted.

R_L = 10 kΩ
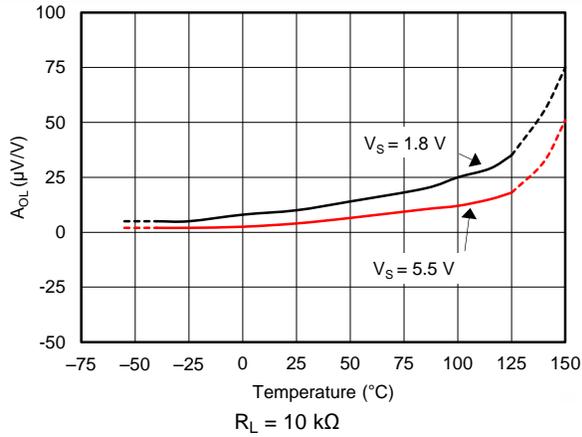
Figure 7. Open-Loop Gain vs Temperature

R_L = 2 kΩ
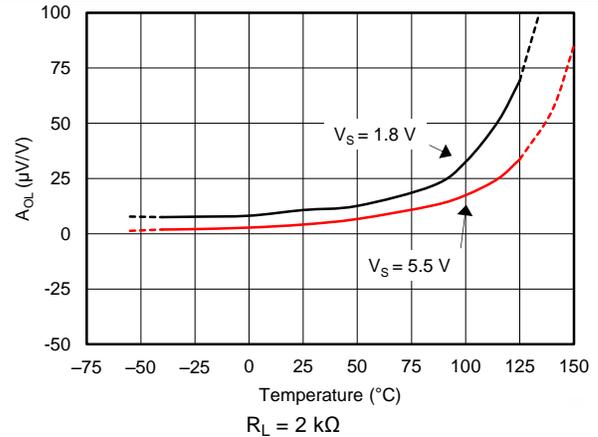
Figure 8. Open-Loop Gain vs Temperature
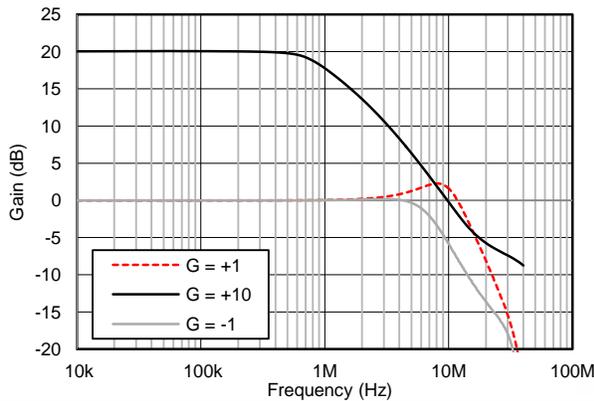
Figure 9. Closed-Loop Gain vs Frequency
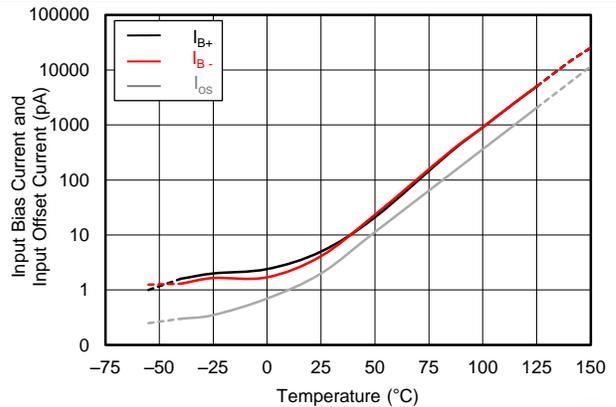
Figure 10. Input Bias and Offset Current vs Temperature

V+ = 2.75 V, V− = −2.75 V
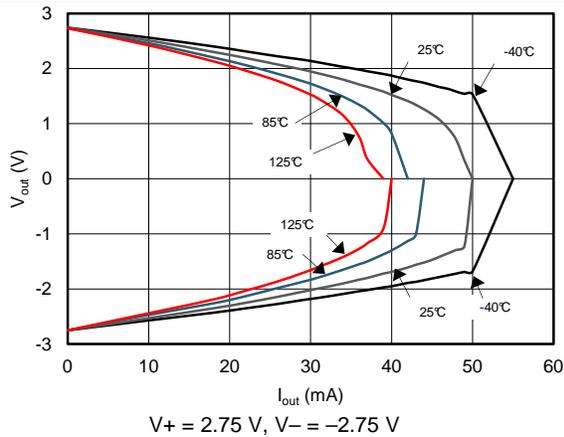
Figure 11. Output Voltage Swing vs Output Current
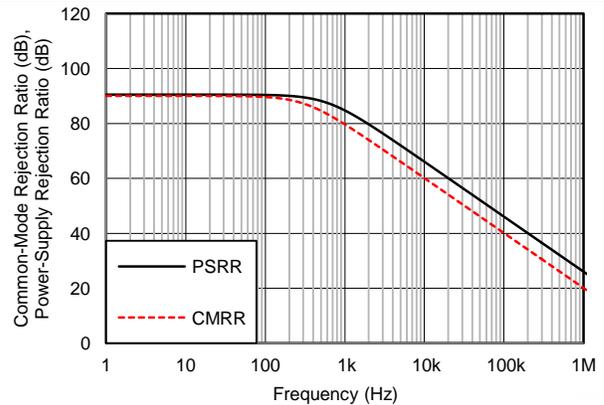
**Figure 12. CMRR and PSRR vs Frequency
(Referred to Input)**

Product Folder Links: *OPA316 OPA2316 OPA2316S OPA4316*

Typical Characteristics (continued)

at T_A = 25°C, V_S = 5.5 V, R_L = 10 kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2, unless otherwise noted.
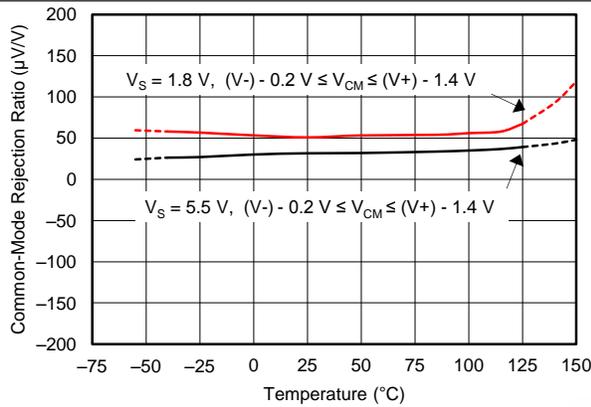
Figure 13. CMRR vs Temperature (Narrow Range)
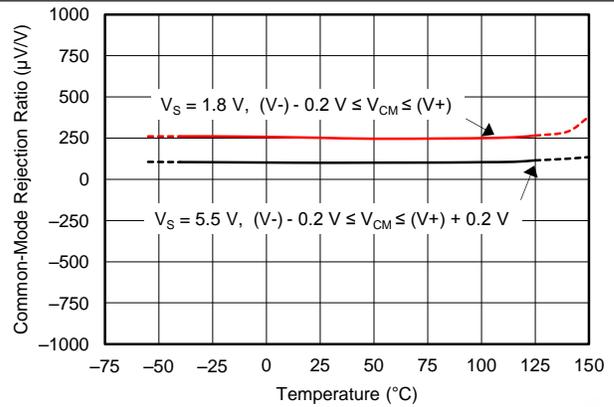
Figure 14. CMRR vs Temperature (Wide Range)
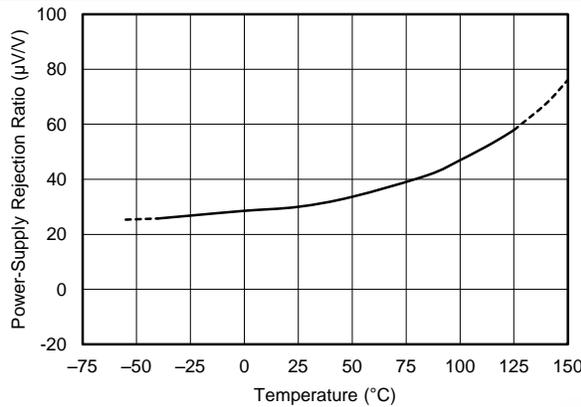
Figure 15. PSRR vs Temperature
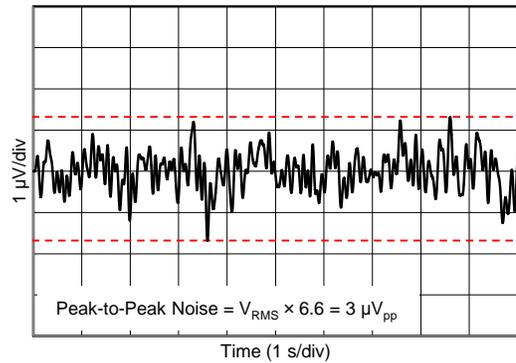
Figure 16. 0.1-Hz to 10-Hz Input Voltage Noise
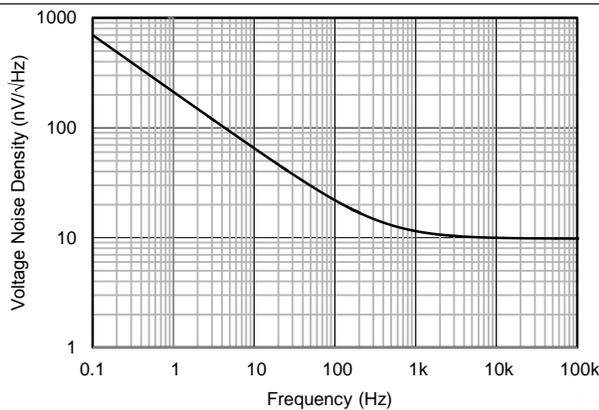
Figure 17. Input Voltage Noise Spectral Density vs Frequency
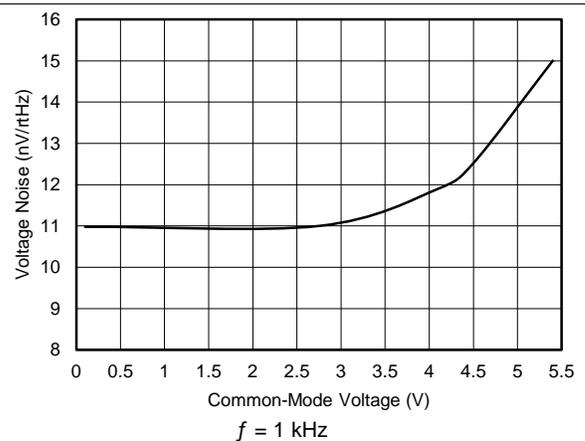
Figure 18. Input Voltage Noise vs Common-Mode Voltage

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Product Folder Links: *OPA316 OPA2316 OPA2316S OPA4316*

Typical Characteristics (continued)

at T_A = 25°C, V_S = 5.5 V, R_L = 10 kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2, unless otherwise noted.

BW = 80 kHz, V_{OUT} = 0.5 V_{RMS}

Figure 19. THD + N vs Frequency

f = 1 kHz, BW = 80 kHz

Figure 20. THD + N vs Amplitude

Figure 21. Quiescent Current vs Supply Voltage

Figure 22. Quiescent Current vs Temperature

Figure 23. Open-Loop Output Impedance vs Frequency

V+ = 2.75 V, V– = –2.75 V, G = –1 V/V

Figure 24. Small-Signal Overshoot vs Load Capacitance

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Typical Characteristics (continued)

at T_A = 25°C, V_S = 5.5 V, R_L = 10 kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2, unless otherwise noted.

V+ = 2.75 V, V− = −2.75 V , G = +1 V/V, R_L = 1 kΩ
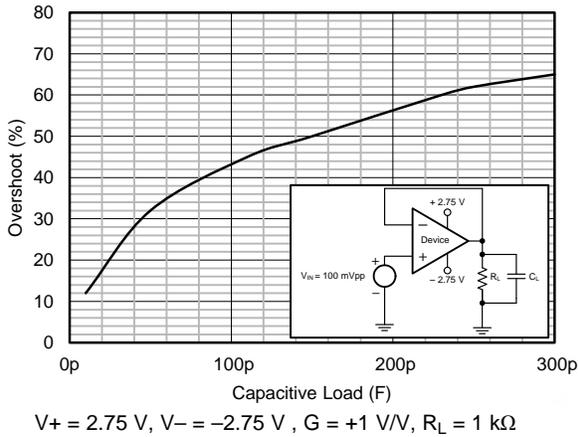
Figure 25. Small-Signal Overshoot vs Load Capacitance

V+ = 2.75 V, V− = −2.75 V
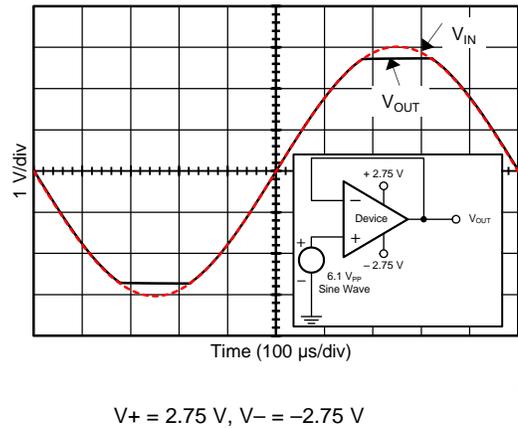
Figure 26. No Phase Reversal

V+ = 2.75 V, V− = −2.75 V , G = −10 V/V
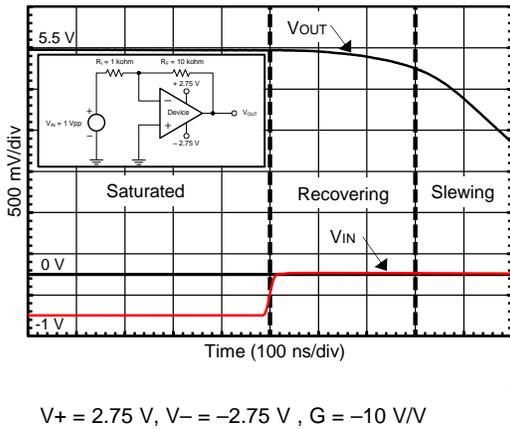
Figure 27. Positive Overload Recovery

V+ = 2.75 V, V− = −2.75 V, G = −10 V/V
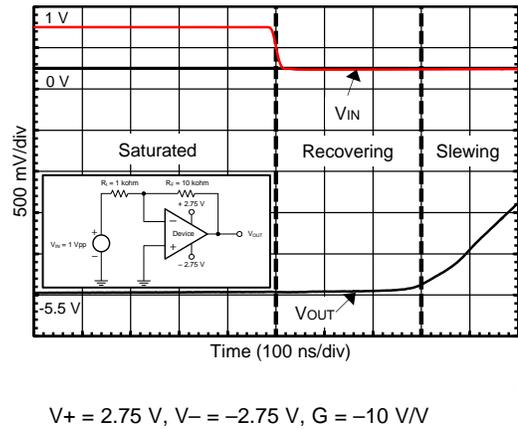
Figure 28. Negative Overload Recovery

V+ = 2.75 V, V− = −2.75 V, G = +1 V/V
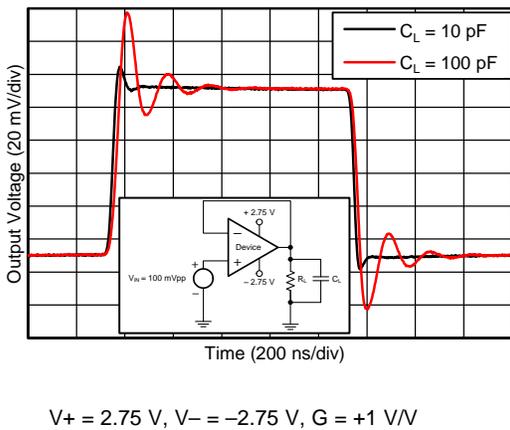
Figure 29. Small-Signal Step Response

V+ = 2.75 V, V− = −2.75 V, C_L = 100 pF, G = +1 V/V
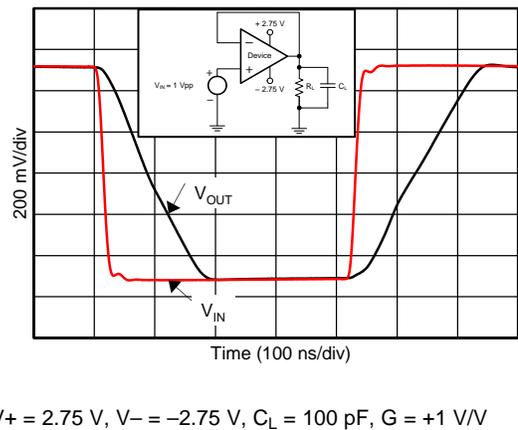
Figure 30. Large-Signal Step Response

Typical Characteristics (continued)

at T_A = 25°C, V_S = 5.5 V, R_L = 10 kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2, unless otherwise noted.

C_L = 100 pF, G = +1 V/V
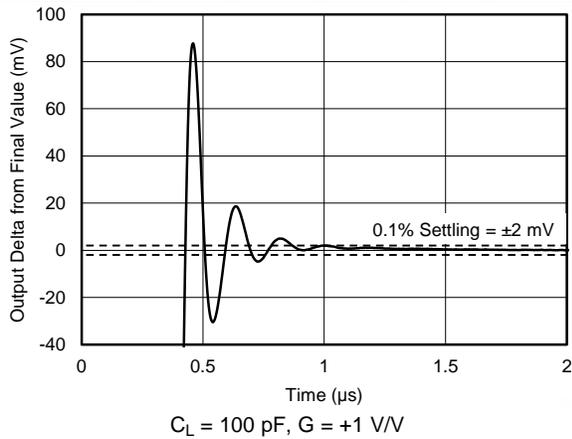
Figure 31. Positive Large-Signal Settling Time

C_L = 100 pF, G = +1 V/V
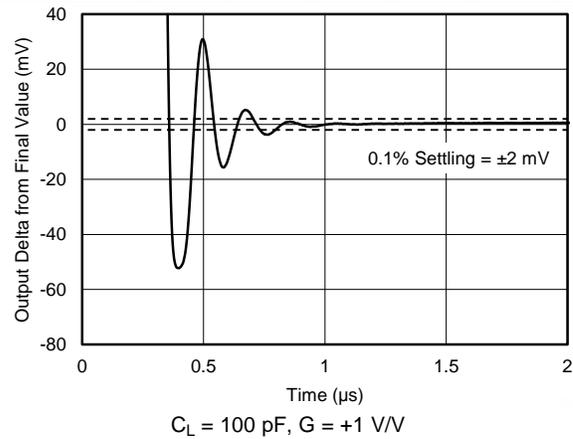
Figure 32. Negative Large-Signal Settling Time
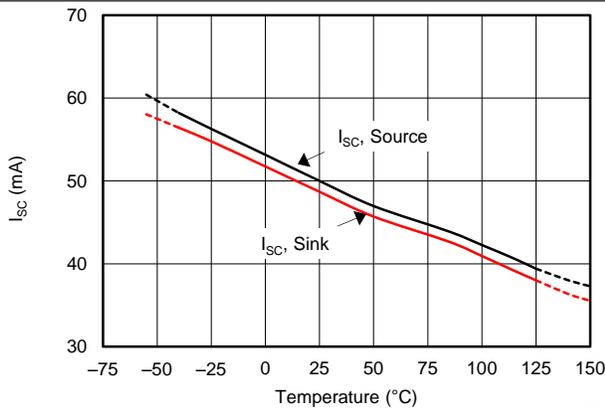
Figure 33. Short-Circuit Current vs Temperature
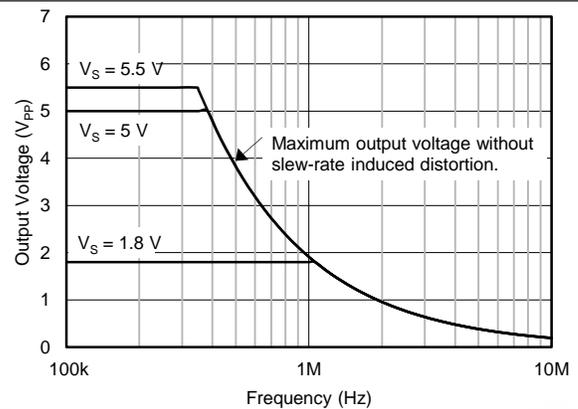
Figure 34. Maximum Output Voltage vs Frequency and Supply Voltage

P_{RF} = −10 dBm
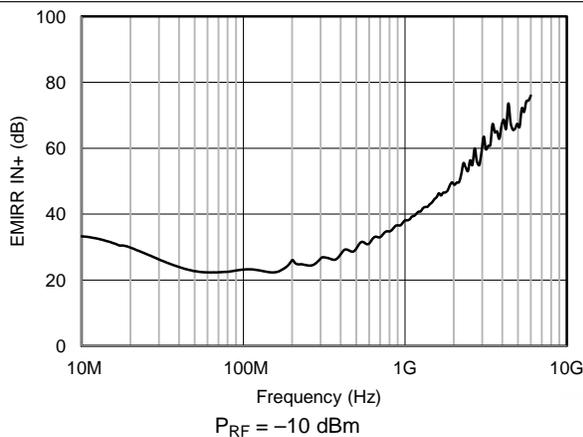
Figure 35. Electromagnetic Interference Rejection Ratio Referred to Noninverting Input (EMIRR IN+) vs Frequency

V+ = 2.75 V, V− = −2.75 V
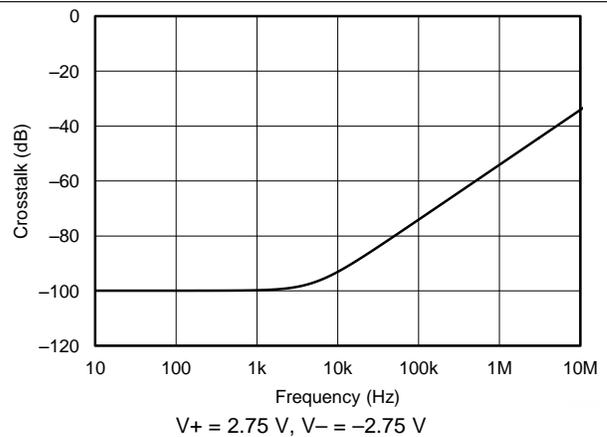
Figure 36. Channel Separation vs Frequency

7 Detailed Description

7.1 Overview

The OPA316 is a family of low-power, rail-to-rail input and output operational amplifiers. These devices operate from 1.8 V to 5.5 V, are unity-gain stable, and are suitable for a wide range of general-purpose applications. The class AB output stage is capable of driving less than or equal to 10-kΩ loads connected to any point between V+ and ground. The input common-mode voltage range includes both rails and allows the OPA316 series to be used in virtually any single-supply application. Rail-to-rail input and output swing significantly increases dynamic range, especially in low-supply applications, and makes them ideal for driving sampling analog-to-digital converters (ADCs).

The OPA316 family features 10-MHz bandwidth and 6-V/µs slew rate with only 400-µA supply current per channel, providing good ac performance at very-low power consumption. DC applications are well served with a very-low input noise voltage of 11 nV/√Hz at 1 kHz, low input bias current (5 pA), and an input offset voltage of 0.5 mV (typical).

7.2 Functional Block Diagram
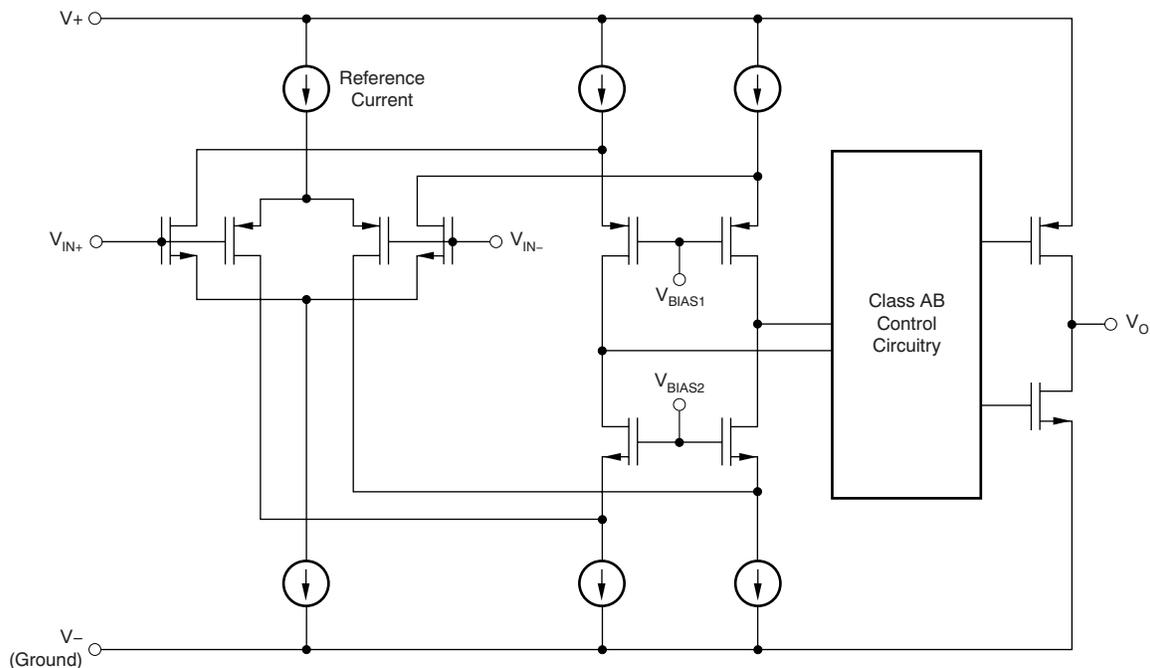
7.3 Feature Description

7.3.1 Operating Voltage

The OPAx316 operational amplifiers are fully specified and ensured for operation from 1.8 V to 5.5 V. In addition, many specifications apply from –40°C to +125°C. Parameters that vary significantly with operating voltages or temperature are illustrated in the *Typical Characteristics* graphs.

7.3.2 Rail-to-Rail Input

The input common-mode voltage range of the OPAx316 series extends 200 mV beyond the supply rails for supply voltages greater than 2.5 V. This performance is achieved with a complementary input stage: an N-channel input differential pair in parallel with a P-channel differential pair, as shown in the *Functional Block Diagram*. The N-channel pair is active for input voltages close to the positive rail, typically (V+) – 1.4 V to 200 mV above the positive supply, whereas the P-channel pair is active for inputs from 200 mV below the negative

Product Folder Links: *OPA316 OPA2316 OPA2316S OPA4316*

Feature Description (continued)

supply to approximately (V+) – 1.4 V. There is a small transition region, typically (V+) – 1.2 V to (V+) – 1 V, in which both pairs are on. This 200-mV transition region can vary up to 200 mV with process variation. Thus, the transition region (both stages on) can range from (V+) – 1.4 V to (V+) – 1.2 V on the low end, up to (V+) – 1 V to (V+) – 0.8 V on the high end. Within this transition region, PSRR, CMRR, offset voltage, offset drift, and THD can be degraded compared to device operation outside this region.

7.3.3 Input and ESD Protection

The OPAx316 incorporates internal ESD protection circuits on all pins. In the case of input and output pins, this protection primarily consists of current-steering diodes connected between the input and power-supply pins. These ESD protection diodes provide in-circuit, input overdrive protection, as long as the current is limited to 10 mA as stated in *Absolute Maximum Ratings*. Figure 37 shows how a series input resistor can be added to the driven input to limit the input current. The added resistor contributes thermal noise at the amplifier input and the value must be kept to a minimum in noise-sensitive applications.
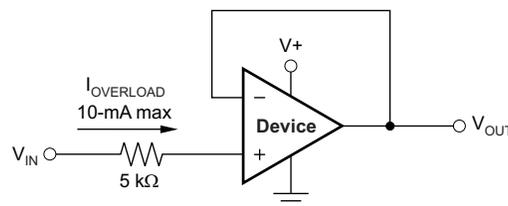
Figure 37. Input Current Protection

7.3.4 Common-Mode Rejection Ratio (CMRR)

CMRR for the OPAx316 is specified in several ways so the user can select the best match for a given application, as shown in *Electrical Characteristics*. First, the data sheet gives the CMRR of the device in the common-mode range below the transition region [V_{CM} < (V+) – 1.4 V]. This specification is the best indicator of device capability when the application requires use of one of the differential input pairs. Second, the CMRR over the entire common-mode range is specified at V_{CM} = –0.2 V to 5.7 V for V_S = 5.5 V. This last value includes the variations shown in Figure 4 through the transition region.

7.3.5 EMI Susceptibility and Input Filtering

Operational amplifiers vary with regard to the susceptibility of the device to electromagnetic interference (EMI). If conducted EMI enters the operational amplifier, the dc offset observed at the amplifier output can shift from its nominal value when EMI is present. This shift is a result of signal rectification associated with the internal semiconductor junctions. Although all operational amplifier pin functions can be affected by EMI, the signal input pins are likely to be the most susceptible. The OPA316 operational amplifier family incorporates an internal input low-pass filter that reduces the amplifier response to EMI. This filter provides both common-mode and differential-mode filtering. The filter is designed for a cutoff frequency of approximately 80 MHz (–3 dB), with a roll-off of 20 dB per decade.

TI developed the ability to accurately measure and quantify the immunity of an operational amplifier over a broad frequency spectrum extending from 10 MHz to 6 GHz. The EMI rejection ratio (EMIRR) metric allows operational amplifiers to be directly compared by the EMI immunity. Figure 35 illustrates the results of this testing on the OPA316 series. For more information, see *EMI Rejection Ratio of Operational Amplifiers* (SBOA128).

7.3.6 Rail-to-Rail Output

Designed as a low-power, low-noise operational amplifier, the OPAx316 delivers a robust output drive capability. A class AB output stage with common-source transistors is used to achieve full rail-to-rail output swing capability. For resistive loads of 10-kΩ, the output swings typically to within 30 mV of either supply rail regardless of the power-supply voltage applied. Different load conditions change the ability of the amplifier to swing close to the rails; see the typical characteristic graph *Output Voltage Swing vs Output Current* (Figure 11).

Product Folder Links: *OPA316 OPA2316 OPA2316S OPA4316*

Feature Description (continued)

7.3.7 Capacitive Load and Stability

The OPAx316 is designed to be used in applications where driving a capacitive load is required. As with all operational amplifiers, there may be specific instances where the OPAx316 can become unstable. The particular operational amplifier circuit configuration, layout, gain, and output loading are some of the factors to consider when establishing whether or not an amplifier is stable in operation. An operational amplifier in the unity-gain (+1 V/V) buffer configuration that drives a capacitive load exhibits a greater tendency to be unstable than an amplifier operated at a higher noise gain. The capacitive load, in conjunction with the operational amplifier output resistance, creates a pole within the feedback loop that degrades the phase margin. The degradation of the phase margin increases as the capacitive loading increases. As a conservative best practice, designing for 25% overshoot (40° phase margin) provides improved stability over process variations. The equivalent series resistance (ESR) of some very-large capacitors (C_L greater than 1 μF) is sufficient to alter the phase characteristics in the feedback loop such that the amplifier remains stable. Increasing the amplifier closed-loop gain allows the amplifier to drive increasingly larger capacitance. This increased capability is evident when observing the overshoot response of the amplifier at higher voltage gains. See the typical characteristic graphs, *Small-Signal Overshoot vs Capacitive Load* (Figure 24, G = −1 V/V) and *Small-Signal Overshoot vs Capacitive Load* (Figure 25, G = +1 V/V).

One technique for increasing the capacitive load drive capability of the amplifier operating in a unity-gain configuration is to insert a small resistor (typically 10 Ω to 20 Ω) in series with the output, as shown in Figure 38. This resistor significantly reduces the overshoot and ringing associated with large capacitive loads. One possible problem with this technique, however, is that a voltage divider is created with the added series resistor and any resistor connected in parallel with the capacitive load. The voltage divider introduces a gain error at the output that reduces the output swing.
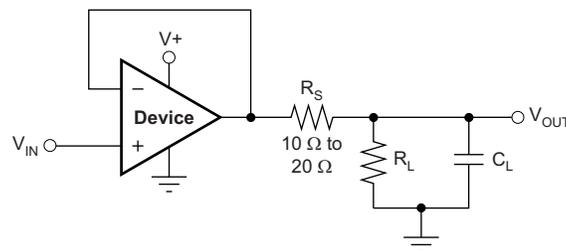
Figure 38. Improving Capacitive Load Drive

7.3.8 Overload Recovery

Overload recovery is defined as the time required for the operational amplifier output to recover from a saturated state to a linear state. The output devices of the operational amplifier enter a saturation region when the output voltage exceeds the rated operating voltage, either because of the high input voltage or the high gain. After the device enters the saturation region, the charge carriers in the output devices require time to return back to the linear state. After the charge carriers return back to the linear state, the device begins to slew at the specified slew rate. Thus, the propagation delay in case of an overload condition is the sum of the overload recovery time and the slew time. The overload recovery time for the OPAx316 is approximately 300 ns.

7.3.9 DFN Package

The OPA2316 (dual version) device uses the DFN style package (also known as SON); this package is a QFN with contacts on only two sides of the package bottom. This leadless package maximizes printed circuit board (PCB) space and offers enhanced thermal and electrical characteristics through an exposed pad. One of the primary advantages of the DFN package is the low, 0.9-mm height. DFN packages are physically small, have a smaller routing area, improved thermal performance, reduced electrical parasitics, and use a pinout scheme that is consistent with other commonly-used packages, such as SOIC and MSOP). Additionally, the absence of external leads eliminates bent-lead issues.

The DFN package can be simply mounted using standard PCB assembly techniques. See *QFN/SON PCB Attachment* (SLUA271) , and *Quad Flatpack No-Lead Logic Packages* (SCBA017).

Feature Description (continued)

NOTE

Connect the exposed lead frame die pad on the bottom of the DFN package to the most negative potential (V–).

7.4 Device Functional Modes

The OPA316, OPA2316, and OPA4316 devices are powered on when the supply is connected. The devices can be operated as a single-supply operational amplifier or a dual-supply amplifier, depending on the application.

The OPA2316S device has a SHDN (enable) pin function referenced to the negative supply voltage of the operational amplifier. A logic level high enables the operational amplifier. A valid logic high is defined as voltage [(V+) – 0.1 V], up to (V+), applied to the SHDN pin. A valid logic low is defined as [(V–) + 0.1 V], down to (V–), applied to the enable pin. The maximum allowed voltage applied to SHDN is 5.5 V with respect to the negative supply, independent of the positive supply voltage. Connect this pin to a valid high or a low voltage or driven, but not left as an open circuit.

The logic input is a high-impedance CMOS input. Both inputs are independently controlled. For battery-operated applications, this feature can be used to greatly reduce the average current and extend battery life.

8 Application and Implementation

> **NOTE**
>
> Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

8.1.1 General Configurations

When receiving low-level signals, the device often requires limiting the bandwidth of the incoming signals into the system. The simplest way to establish this limited bandwidth is to place an RC filter at the noninverting pin of the amplifier, as Figure 39 shows.

$$f_{-3\,dB} = \frac{1}{2\pi R_1 C_1}$$
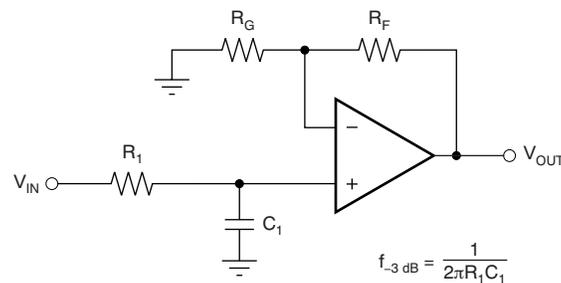
$$\frac{V_{OUT}}{V_{IN}} = \left(1 + \frac{R_F}{R_G}\right)\left(\frac{1}{1 + sR_1C_1}\right)$$

Figure 39. Single-Pole Low-Pass Filter

If even more attenuation is needed, the device requires a multiple-pole filter. The Sallen-Key filter can be used for this task, as Figure 40 shows. For best results, the amplifier must have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to follow this guideline can result in phase shift of the amplifier.

$R_1 = R_2 = R$
$C_1 = C_2 = C$
Q = Peaking factor
(Butterworth Q = 0.707)

$$f_{-3\,dB} = \frac{1}{2\pi RC}$$

$$R_G = \frac{R_F}{\left(2 - \frac{1}{Q}\right)}$$
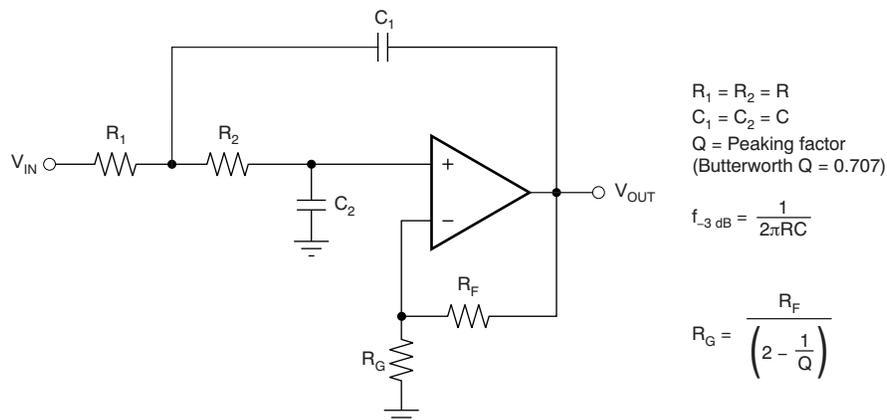
Figure 40. Two-Pole, Low-Pass, Sallen-Key Filter

Product Folder Links: *OPA316 OPA2316 OPA2316S OPA4316*

8.2 Typical Application

Some applications require differential signals. Figure 41 shows a simple circuit to convert a single-ended input of 0.1 V to 2.4 V into a differential output of ±2.3 V on a single 2.7-V supply. The output range is intentionally limited to maximize linearity. The circuit is composed of two amplifiers. One amplifier functions as a buffer and creates a voltage, VOUT+. The second amplifier inverts the input and adds a reference voltage to generate VOUT−. VOUT+ and VOUT− range from 0.1 V to 2.4 V. The difference, VDIFF, is the difference between VOUT+ and VOUT− which makes the differential output voltage range 2.3 V.
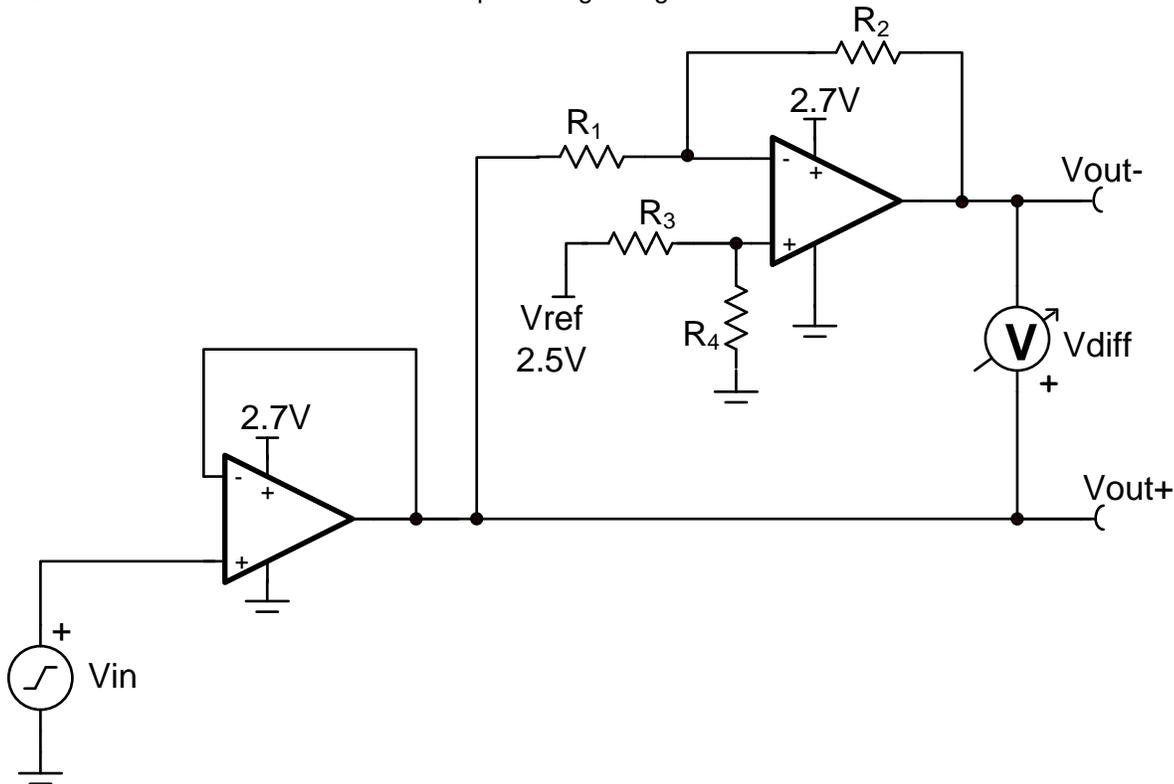
Figure 41. Schematic for a Single-Ended Input to Differential Output Conversion

8.2.1 Design Requirements

Table 1 lists the design requirements:

Table 1. Design Parameters

DESIGN PARAMETER	VALUE
Supply voltage	2.7 V
Reference voltage	2.5 V
Input voltage	0.1 V to 2.4 V
Output differential voltage	±2.3 V
Output common-mode voltage	1.25 V
Small-signal bandwidth	5 MHz

8.2.2 Detailed Design Procedure

The circuit in Figure 41 takes a single-ended input signal, VIN, and generates two output signals, VOUT+ and VOUT− using two amplifiers and a reference voltage, VREF. VOUT+ is the output of the first amplifier and is a buffered version of the input signal, VIN (as shown in Equation 1). VOUT− is the output of the second amplifier which uses VREF to add an offset voltage to VIN and feedback to add inverting gain. The transfer function for VOUT− is given in Equation 2.

$$V_{out+} = V_{in} \tag{1}$$

$$V_{out-} = V_{ref} \times \left(\frac{R4}{R3+R4} \right) \times \left(1 + \frac{R2}{R1} \right) - V_{in} \times \frac{R2}{R1}$$

(2)

The differential output signal, VDIFF, is the difference between the two single-ended output signals, VOUT+ and VOUT–. Equation 3 shows the transfer function for VDIFF. Using conditions in Equation 4 and Equation 5 and applying the conditions that $R_1 = R_2$ and $R_3 = R_4$, the transfer function is simplified into Equation 6. Using this configuration, the maximum input signal is equal to the reference voltage, and the maximum output of each amplifier is equal to VREF. The differential output range is 2 × VREF. Furthermore, the common-mode voltage is one half of VREF, as shown in Equation 7.

$$V_{diff} = V_{out+} - V_{out-} = V_{in} \times \left(1 + \frac{R2}{R1} \right) - V_{ref} \times \left(\frac{R4}{R3 + R4} \right) \times \left(1 + \frac{R2}{R1} \right)$$

(3)

$$V_{out+} = V_{in}$$

(4)

$$V_{out-} = V_{ref} - V_{in}$$

(5)

$$V_{diff} = 2 \times V_{in} - V_{ref}$$

(6)

$$V_{cm} = \left(\frac{V_{out+} + V_{out-}}{2} \right) = \frac{1}{2} V_{ref}$$

(7)

8.2.2.1 Amplifier Selection

Linearity over the input range is key for good dc accuracy. The common-mode input range and output swing limitations determine the linearity. In general, an amplifier with rail-to-rail input and output swing is required. Bandwidth is a key concern for this design, so the OPAx316 is selected because the bandwidth is greater than the target of 5 MHz. The bandwidth and power ratio makes this device power efficient and the low offset and drift ensure good accuracy for moderate precision applications.

8.2.2.2 Passive Component Selection

Because the transfer function of VOUT– is heavily reliant on resistors (R_1, R_2, R_3, and R_4), use resistors with low tolerances to maximize performance and minimize error. This design uses resistors with resistance values of 49.9 kΩ and tolerances of 0.1%. However, if the noise of the system is a key parameter, smaller resistance values (6 kΩ or lower) can be selected to keep the overall system noise low. This ensures that the noise from the resistors is lower than the amplifier noise.

8.2.3 Application Curves

The measured transfer functions in Figure 42, Figure 43, and Figure 44 are generated by sweeping the input voltage from 0.1 V to 2.4 V. The full input range is actually 0 V to 2.5 V, but is restricted by 0.1 V to maintain optimal linearity. For more details on this design and other alternative devices that can be used in place of the OPAx316, see (*Single-Ended Input to Differential Output Conversion Circuit Reference Design* (TIPD131).
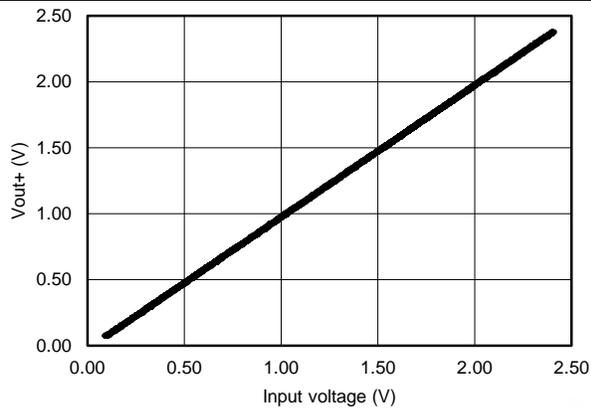
Figure 42. VOUT+ vs Input Voltage
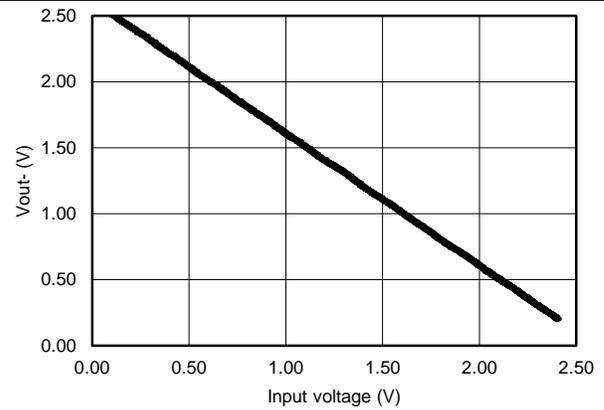
Figure 43. VOUT– vs Input Voltage
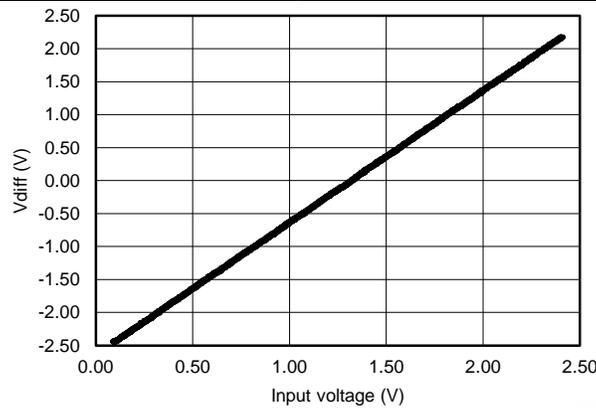
Figure 44. VDIFF vs Input Voltage

9 Power Supply Recommendations

The OPAx316 is specified for operation from 1.8 V to 5.5 V (±0.9 V to ±2.75 V); many specifications apply from –40°C to +125°C. *Typical Characteristics* presents parameters that can exhibit significant variance with regard to operating voltage or temperature.

CAUTION

Supply voltages larger than 7 V can permanently damage the device (see the *Absolute Maximum Ratings*) table.

Place 0.1-μF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more information on bypass capacitor placement, see *Layout Guidelines*.

10 Layout

10.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and the operational amplifier. Bypass capacitors reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
  - Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for single-supply applications.
- Separate grounding for analog and digital portions of the circuitry is one of the simplest and most effective methods of noise suppression. One or more layers on multilayer PCBs are typically devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Take care to physically separate digital and analog grounds, paying attention to the flow of the ground current. For more detailed information, see *Circuit Board Layout Techniques* (SLOA089).
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicularly is much better than crossing in parallel with the noisy trace.
- Place the external components as close to the device as possible. Keeping RF and RG close to the inverting input minimizes parasitic capacitance, as shown in *Layout Example* .
- Keep the length of input traces as short as possible. Remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

10.2 Layout Example

Figure 45. Operational Amplifier Board Layout for Noninverting Configuration

Product Folder Links: *OPA316 OPA2316 OPA2316S OPA4316*

11   Device and Documentation Support

11.1   Documentation Support

11.1.1   Related Documentation

For related documentation see the following:
* *EMI Rejection Ratio of Operational Amplifiers* (SBOA128).
* *QFN/SON PCB Attachment* (SLUA271).
* *Quad Flatpack No-Lead Logic Packages* (SCBA017).
* *Single-Ended Input to Differential Output Conversion Circuit Reference Design* (TIPD131).
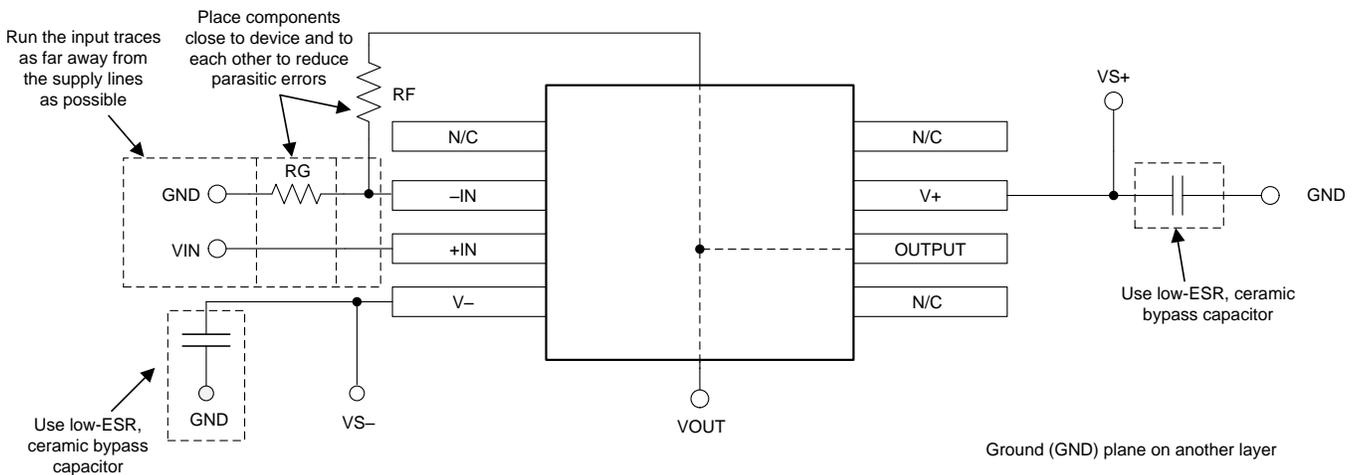* *Circuit Board Layout Techniques* (SLOA089).

11.2   Related Links

The following table lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
OPA316	Click here	Click here	Click here	Click here	Click here
OPA2316	Click here	Click here	Click here	Click here	Click here
OPA2316S	Click here	Click here	Click here	Click here	Click here
OPA4316	Click here	Click here	Click here	Click here	Click here

11.3   Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.4   Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.5   Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

11.6   Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.7   Glossary

SLYZ022 — *TI Glossary*.
   This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
OPA2316ID	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O2316
OPA2316ID.B	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O2316
OPA2316IDGK	Active	Production	VSSOP (DGK) | 8	80 | TUBE	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	OVMQ
OPA2316IDGK.B	Active	Production	VSSOP (DGK) | 8	80 | TUBE	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	OVMQ
OPA2316IDGKR	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	OVMQ
OPA2316IDGKR.B	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OVMQ
OPA2316IDR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O2316
OPA2316IDR.B	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O2316
OPA2316IDRGR	Active	Production	SON (DRG) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SMD
OPA2316IDRGR.B	Active	Production	SON (DRG) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SMD
OPA2316IDRGRG4	Active	Production	SON (DRG) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SMD
OPA2316IDRGRG4.B	Active	Production	SON (DRG) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SMD
OPA2316IDRGT	Active	Production	SON (DRG) | 8	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SMD
OPA2316IDRGT.B	Active	Production	SON (DRG) | 8	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SMD
OPA2316SIDGS	Active	Production	VSSOP (DGS) | 10	80 | TUBE	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	SMG
OPA2316SIDGS.B	Active	Production	VSSOP (DGS) | 10	80 | TUBE	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	SMG
OPA2316SIDGSR	Active	Production	VSSOP (DGS) | 10	2500 | LARGE T&R	Yes	NIPDAUAG | SN	Level-2-260C-1 YEAR	-40 to 125	SMG
OPA2316SIDGSR.B	Active	Production	VSSOP (DGS) | 10	2500 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SMG
OPA2316SIRUGR	Active	Production	X2QFN (RUG) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1QU
OPA2316SIRUGR.B	Active	Production	X2QFN (RUG) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1QU
OPA2316SIRUGRG4	Active	Production	X2QFN (RUG) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1QU
OPA2316SIRUGRG4.B	Active	Production	X2QFN (RUG) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1QU
OPA2316SIRUGT	Active	Production	X2QFN (RUG) | 10	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1QU
OPA2316SIRUGT.B	Active	Production	X2QFN (RUG) | 10	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1QU
OPA316IDBVR	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SLE
OPA316IDBVR.B	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SLE
OPA316IDBVT	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SLE
OPA316IDBVT.B	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SLE
OPA316IDBVTG4	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SLE

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
OPA316IDBVTG4.B	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SLE
OPA316IDCKR	Active	Production	SC70 (DCK) | 5	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	SLD
OPA316IDCKR.B	Active	Production	SC70 (DCK) | 5	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	SLD
OPA316IDCKT	Active	Production	SC70 (DCK) | 5	250 | SMALL T&R	Yes	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	SLD
OPA316IDCKT.B	Active	Production	SC70 (DCK) | 5	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	SLD
OPA316IDCKTG4	Active	Production	SC70 (DCK) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SLD
OPA316IDCKTG4.B	Active	Production	SC70 (DCK) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SLD
OPA4316ID	Active	Production	SOIC (D) | 14	50 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O4316D
OPA4316ID.B	Active	Production	SOIC (D) | 14	50 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O4316D
OPA4316IDR	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O4316D
OPA4316IDR.B	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O4316D
OPA4316IDRG4	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O4316D
OPA4316IDRG4.B	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O4316D
OPA4316IPW	Active	Production	TSSOP (PW) | 14	90 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4316
OPA4316IPW.B	Active	Production	TSSOP (PW) | 14	90 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4316
OPA4316IPWR	Active	Production	TSSOP (PW) | 14	2000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4316
OPA4316IPWR.B	Active	Production	TSSOP (PW) | 14	2000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4316
OPA4316IPWRG4	Active	Production	TSSOP (PW) | 14	2000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4316
OPA4316IPWRG4.B	Active	Production	TSSOP (PW) | 14	2000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4316

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF OPA2316, OPA316, OPA4316 :

- Automotive : OPA2316-Q1, OPA316-Q1, OPA4316-Q1

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

User Direction of Feed

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA2316IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.25	3.35	1.25	8.0	12.0	Q1
OPA2316IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA2316IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA2316IDRGR	SON	DRG	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
OPA2316IDRGRG4	SON	DRG	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
OPA2316IDRGT	SON	DRG	8	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
OPA2316SIDGSR	VSSOP	DGS	10	2500	330.0	12.4	5.25	3.35	1.25	8.0	12.0	Q1
OPA2316SIRUGR	X2QFN	RUG	10	3000	180.0	8.4	1.75	2.25	0.55	4.0	8.0	Q1
OPA2316SIRUGRG4	X2QFN	RUG	10	3000	180.0	8.4	1.75	2.25	0.55	4.0	8.0	Q1
OPA2316SIRUGT	X2QFN	RUG	10	250	180.0	8.4	1.75	2.25	0.55	4.0	8.0	Q1
OPA316IDBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
OPA316IDBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
OPA316IDBVTG4	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
OPA316IDCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
OPA316IDCKT	SC70	DCK	5	250	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
OPA316IDCKTG4	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA4316IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
OPA4316IDRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
OPA4316IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
OPA4316IPWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA2316IDGKR	VSSOP	DGK	8	2500	366.0	364.0	50.0
OPA2316IDGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
OPA2316IDR	SOIC	D	8	2500	353.0	353.0	32.0
OPA2316IDRGR	SON	DRG	8	3000	346.0	346.0	33.0
OPA2316IDRGRG4	SON	DRG	8	3000	346.0	346.0	33.0
OPA2316IDRGT	SON	DRG	8	250	182.0	182.0	20.0
OPA2316SIDGSR	VSSOP	DGS	10	2500	366.0	364.0	50.0
OPA2316SIRUGR	X2QFN	RUG	10	3000	210.0	185.0	35.0
OPA2316SIRUGRG4	X2QFN	RUG	10	3000	210.0	185.0	35.0
OPA2316SIRUGT	X2QFN	RUG	10	250	210.0	185.0	35.0
OPA316IDBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
OPA316IDBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
OPA316IDBVTG4	SOT-23	DBV	5	250	180.0	180.0	18.0
OPA316IDCKR	SC70	DCK	5	3000	210.0	185.0	35.0
OPA316IDCKT	SC70	DCK	5	250	210.0	185.0	35.0
OPA316IDCKTG4	SC70	DCK	5	250	180.0	180.0	18.0
OPA4316IDR	SOIC	D	14	2500	353.0	353.0	32.0
OPA4316IDRG4	SOIC	D	14	2500	353.0	353.0	32.0

PACKAGE MATERIALS INFORMATION

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA4316IPWR	TSSOP	PW	14	2000	353.0	353.0	32.0
OPA4316IPWRG4	TSSOP	PW	14	2000	353.0	353.0	32.0

PACKAGE MATERIALS INFORMATION

TUBE
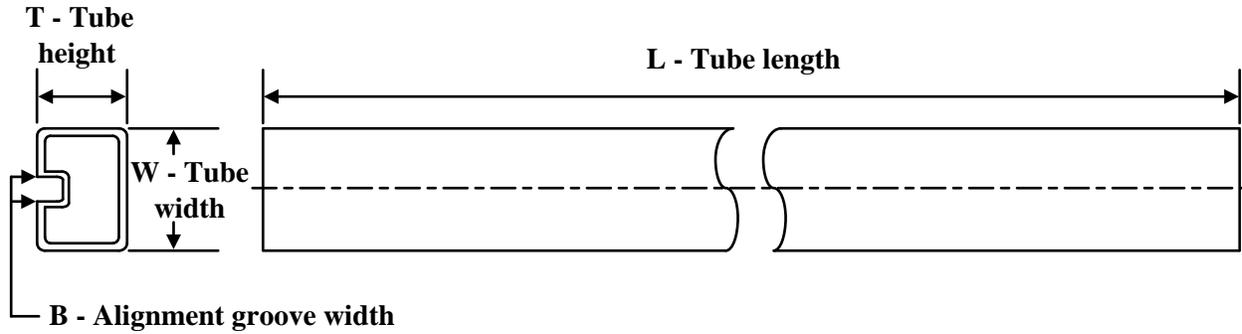
*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
OPA2316ID	D	SOIC	8	75	506.6	8	3940	4.32
OPA2316ID.B	D	SOIC	8	75	506.6	8	3940	4.32
OPA2316IDGK	DGK	VSSOP	8	80	330	6.55	500	2.88
OPA2316IDGK.B	DGK	VSSOP	8	80	330	6.55	500	2.88
OPA2316SIDGS	DGS	VSSOP	10	80	330	6.55	500	2.88
OPA2316SIDGS.B	DGS	VSSOP	10	80	330	6.55	500	2.88
OPA4316ID	D	SOIC	14	50	507	8	3940	4.32
OPA4316ID.B	D	SOIC	14	50	507	8	3940	4.32
OPA4316IPW	PW	TSSOP	14	90	530	10.2	3600	3.5
OPA4316IPW.B	PW	TSSOP	14	90	530	10.2	3600	3.5

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4225794/A

A | 3.1 / 2.9 | B

PIN 1 INDEX AREA

3.1 / 2.9

0.8 / 0.7

C

SEATING PLANE

0.05 / 0.00

△ | 0.08 | C

EXPOSED THERMAL PAD

1.2 ± 0.1

(0.2) TYP

4

5

2X [1.5]

2 ± 0.1

1

8

6X [0.5]

8X 0.3 / 0.2

PIN 1 ID

8X 0.6 / 0.4

⊕ | 0.1 Ⓜ | C | A | B
0.08 Ⓜ | C
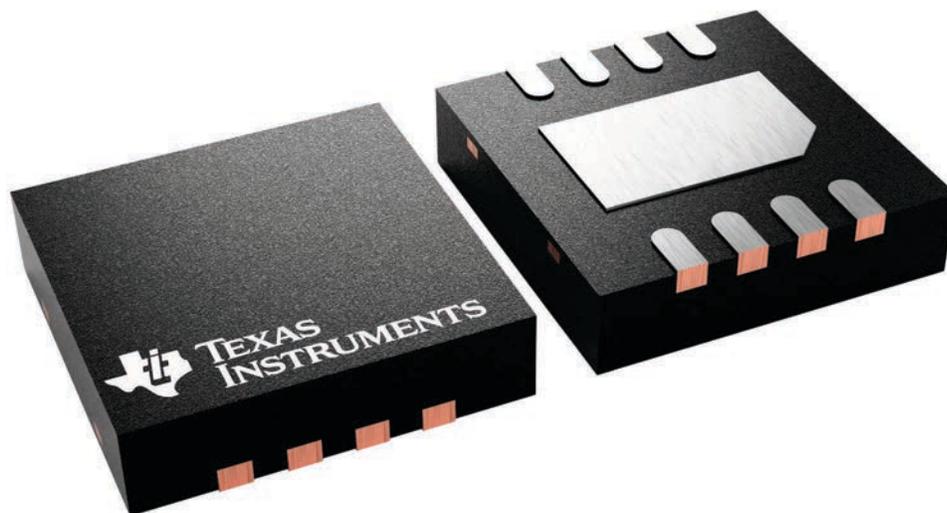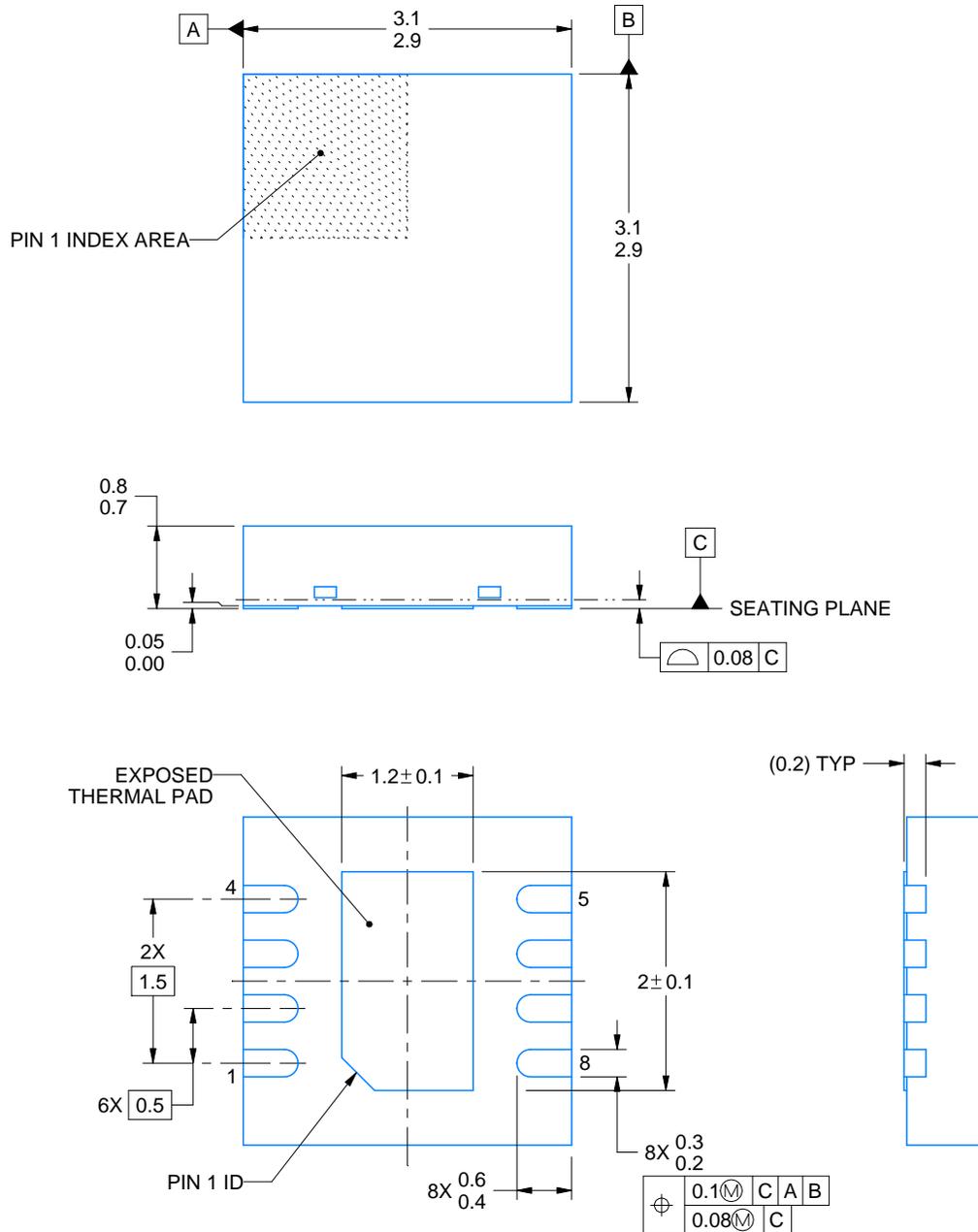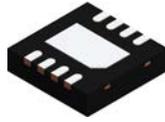
4218885/A   03/2020

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

8X (0.7)

(1.2)

SYMM

8X (0.25)

1

SYMM

6X (0.5)

4

(R0.05) TYP

(Ø 0.2) VIA TYP

8

(2)

(0.75)

5

(0.35)

(2.7)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:20X

0.07 MAX
ALL AROUND

EXPOSED
METAL

SOLDER MASK
OPENING

METAL

NON SOLDER MASK
DEFINED
(PREFERRED)

0.07 MIN
ALL AROUND

EXPOSED
METAL

METAL UNDER
SOLDER MASK
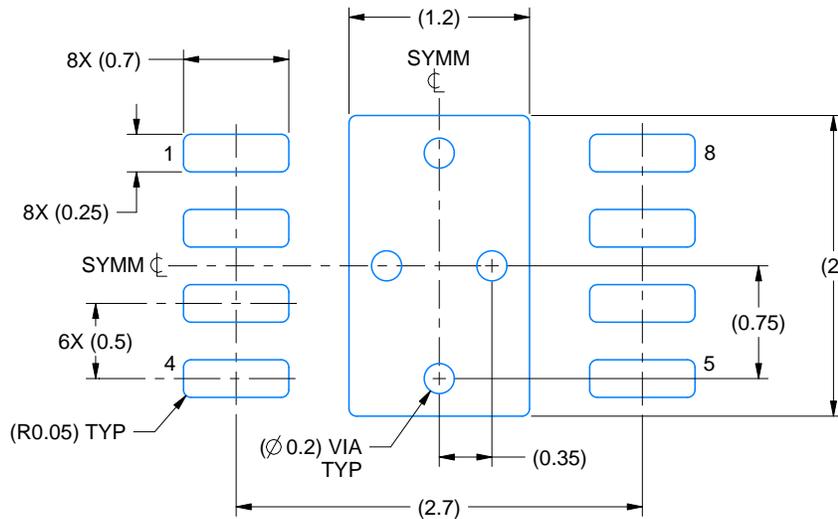
SOLDER MASK
OPENING

SOLDER MASK
DEFINED
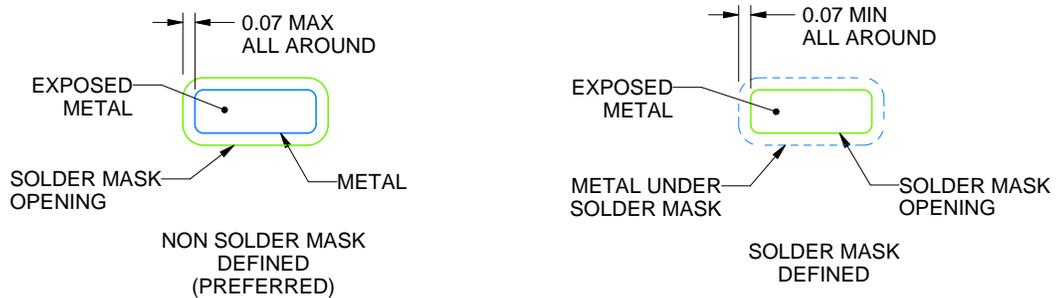
SOLDER MASK DETAILS

4218885/A   03/2020

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

8X (0.7)

SYMM

METAL
TYP

8X (0.25)   1

8

SYMM

6X (0.5)

4

5

(R0.05) TYP

(1.13)

(1.79)

(2.7)
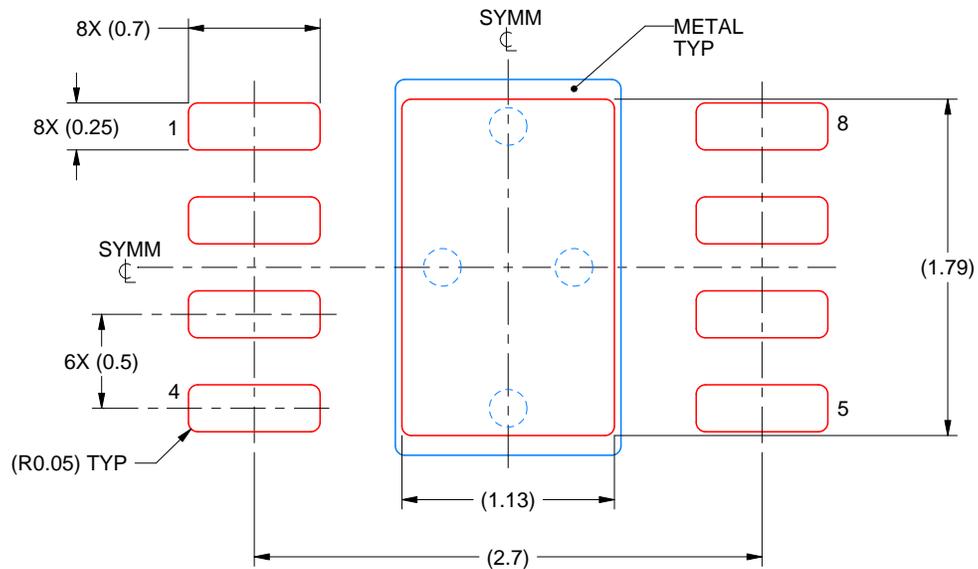
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
84% PRINTED SOLDER COVERAGE BY AREA
SCALE:25X

4218885/A   03/2020

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate
   design recommendations.

A

6.2
5.8 TYP

PIN 1 ID
AREA

1

14

12X 1.27

8.75
8.55
NOTE 3

2X
7.62

7

8

14X 0.51
0.31

B

4.0
3.8
NOTE 4

⊕ 0.25ⓂC A B

C

SEATING PLANE

⌒ 0.1 C

1.75 MAX

SEE DETAIL A

0.25
0.13 TYP

0.25
GAGE PLANE

0° - 8°

1.27
0.40

0.25
0.10

DETAIL A
TYPICAL

4220718/A 09/2016
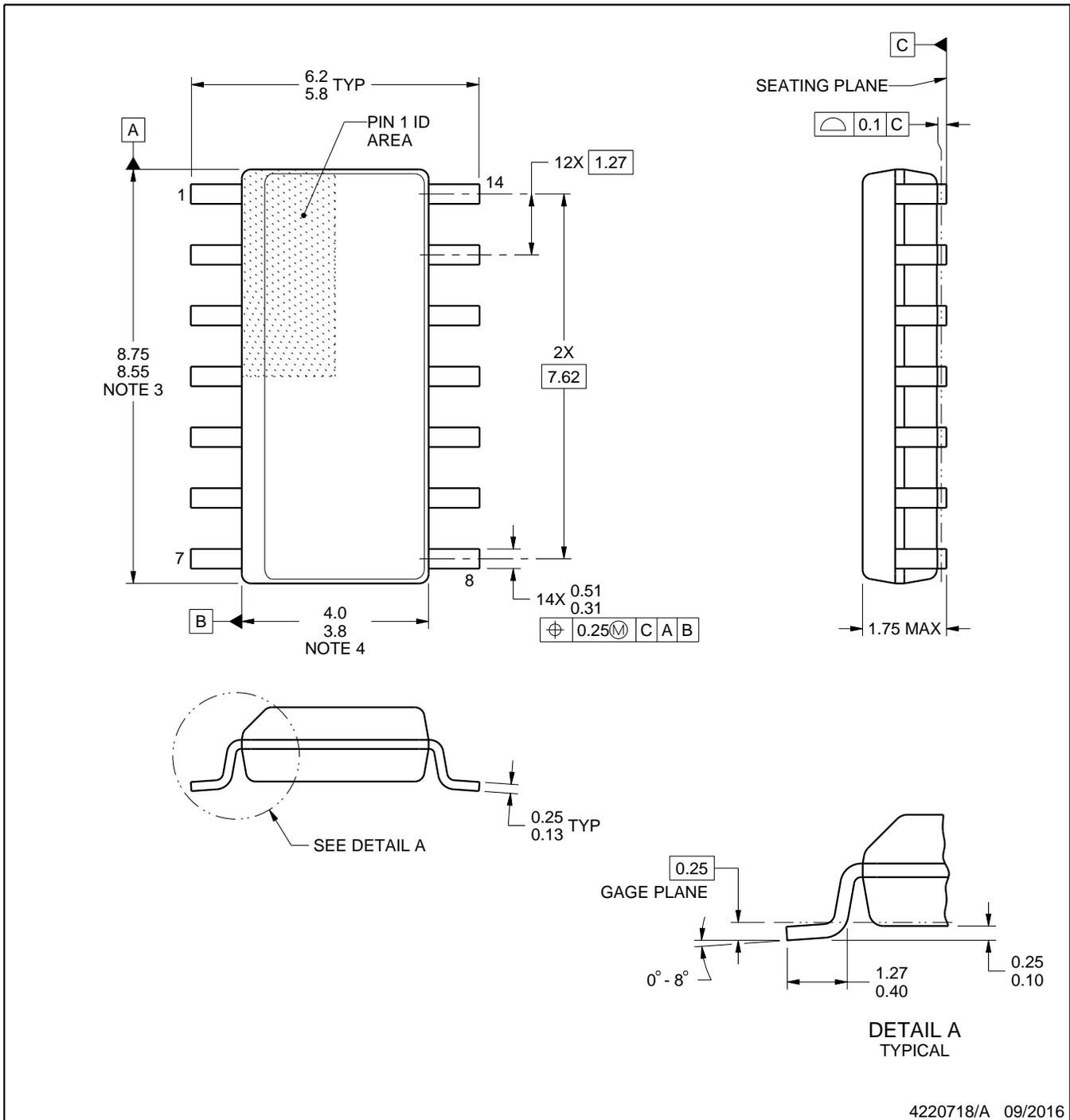
NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
5. Reference JEDEC registration MS-012, variation AB.

TEXAS INSTRUMENTS
www.ti.com

14X (1.55)

1

14X (0.6)

12X (1.27)

SYMM

14

SYMM

7

8

(R0.05)
TYP

(5.4)

LAND PATTERN EXAMPLE
SCALE:8X

SOLDER MASK
OPENING

METAL

0.07 MAX
ALL AROUND

NON SOLDER MASK
DEFINED

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

0.07 MIN
ALL AROUND

SOLDER MASK
DEFINED
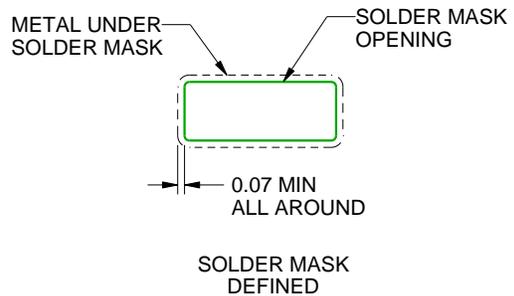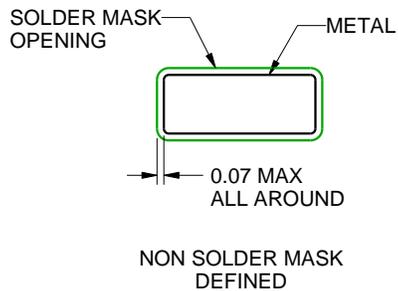
SOLDER MASK DETAILS

4220718/A   09/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

14X (1.55)

1

14X (0.6)

SYMM
℄

14

12X (1.27)

SYMM
℄

7

8

(5.4)
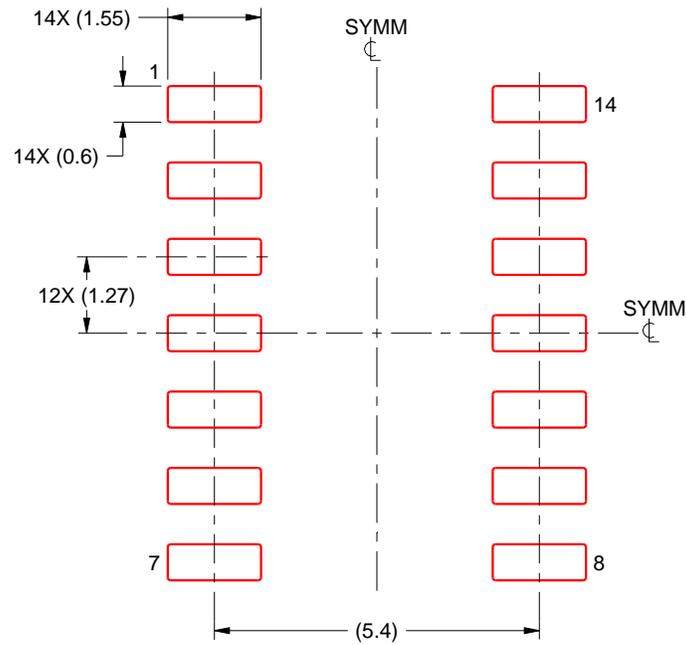
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:8X

4220718/A   09/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

RUG 10

1.5 x 2, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4231768/A

B | 1.55 / 1.45 | A

PIN 1 INDEX AREA

2.05 / 1.95

0.40 / 0.34

C

SEATING PLANE

| 0.05 | C |

0.05 / 0.00

2X 0.35 / 0.25

| ⊕ | 0.1 Ⓜ | C | A | B |
| | 0.05 Ⓜ | C | | |

SYMM ℄

5

4

6

(0.127) TYP

4X 0.3 / 0.2

| ⊕ | 0.1 Ⓜ | C | A | B |
| | 0.05 Ⓜ | C | | |

2X 1.5

SYMM ℄

6X 0.5

4X 0.25 / 0.15

| ⊕ | 0.1 Ⓜ | C | A | B |
| | 0.05 Ⓜ | C | | |

1

9

2X 0.45 / 0.35

10

PIN 1 ID
(45° X 0.1)
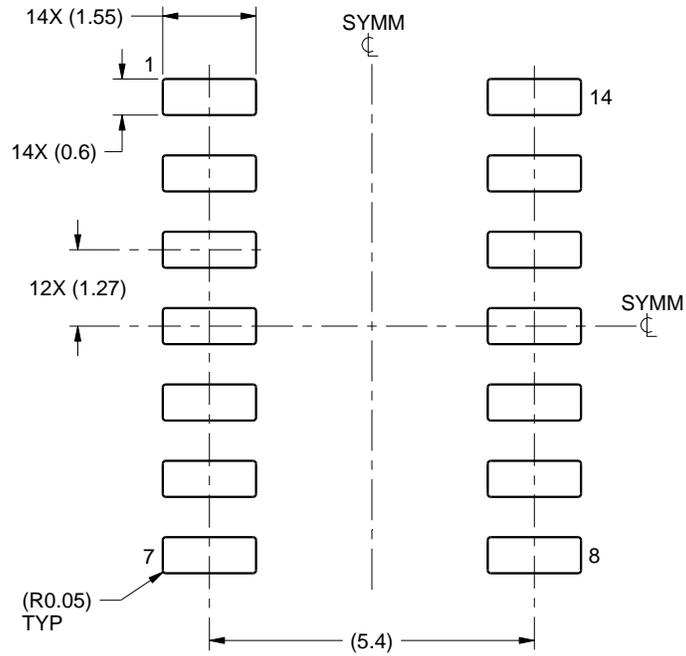
8X 0.4 / 0.3
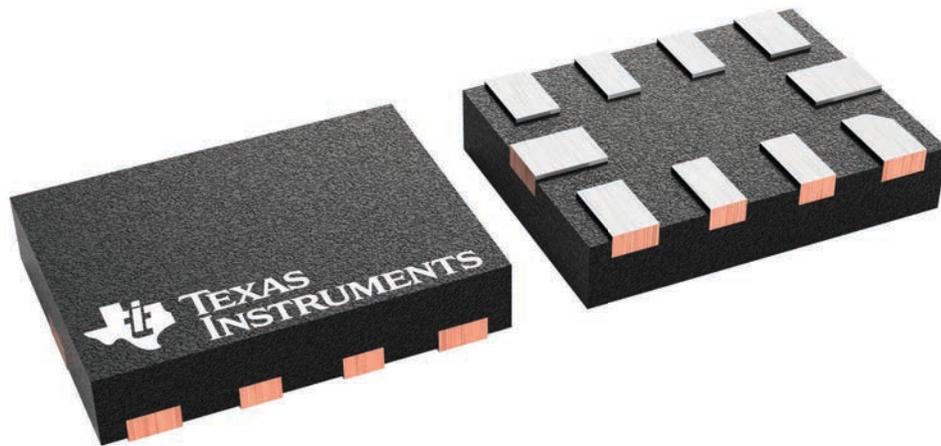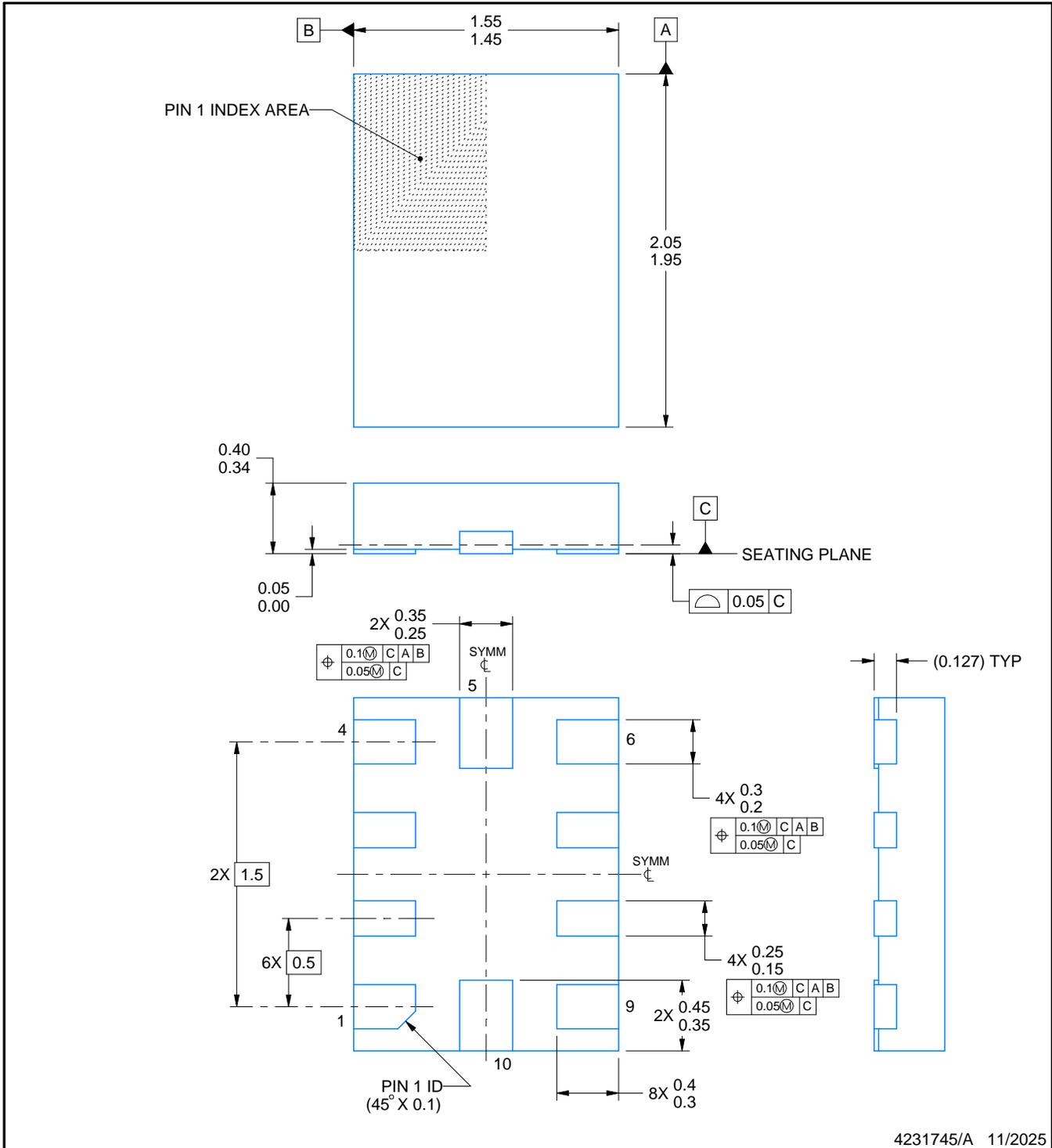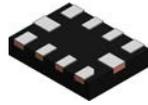
4231745/A   11/2025

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

RUG0010A

2X (0.3)

SYMM
℄

10

SEE SOLDER MASK
DETAIL

8X (0.55)

4X (0.25)

1

9

4X (0.2)

6X (0.5)

SYMM
℄

(1.8)

(R0.05) TYP

4

6

2X (0.6)

5

(1.35)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 35X

0.05 MAX
ALL AROUND

METAL EDGE

EXPOSED METAL

SOLDER MASK
OPENING

NON SOLDER MASK
DEFINED
(PREFERRED)

0.05 MIN
ALL AROUND

METAL UNDER
SOLDER MASK

EXPOSED
METAL

SOLDER MASK
OPENING

SOLDER MASK DEFINED

SOLDER MASK DETAILS

4231745/A   11/2025

NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

2X (0.3)

SYMM

10

8X (0.55)

4X (0.25)

1

9

4X (0.2)

SYMM

6X (0.5)

(1.8)

(R0.05) TYP

4

6

2X (0.6)

5

(1.35)

SOLDER PASTE EXAMPLE
BASED ON 0.125 MM THICK STENCIL
SCALE: 35X

4231745/A   11/2025

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate
   design recommendations.

5.05
4.75 TYP

A

PIN 1 ID
AREA

1

3.1
2.9
NOTE 3

5

B

3.1
2.9
NOTE 4

10

8X [0.5]

2X
[2]

6

10X 0.27
0.17

[⊕ 0.1Ⓜ C AⓈ BⓈ]

C

SEATING PLANE

[⌒ 0.1 C]

1.1 MAX

SEE DETAIL A

0.23
0.13 TYP

0.25

GAGE PLANE

0° - 8°

0.7
0.4

0.15
0.05

DETAIL A
TYPICAL

4221984/A   05/2015

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing
   per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
   exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187, variation BA.

10X (1.45)

10X (0.3)

1

SYMM

(R0.05)
TYP

10

SYMM

8X (0.5)

5

6

(4.4)
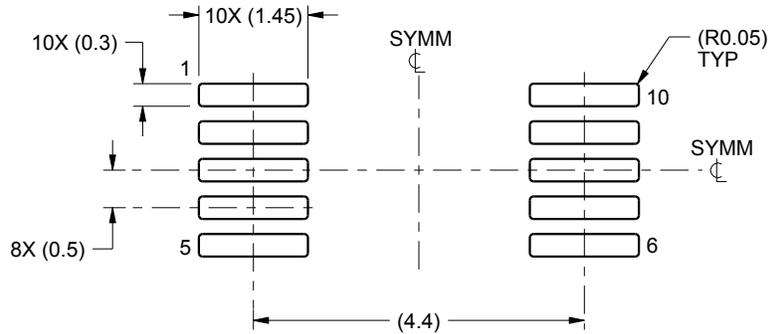
LAND PATTERN EXAMPLE
SCALE:10X

SOLDER MASK
OPENING

METAL

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

0.05 MAX
ALL AROUND

0.05 MIN
ALL AROUND

NON SOLDER MASK
DEFINED

SOLDER MASK
DEFINED
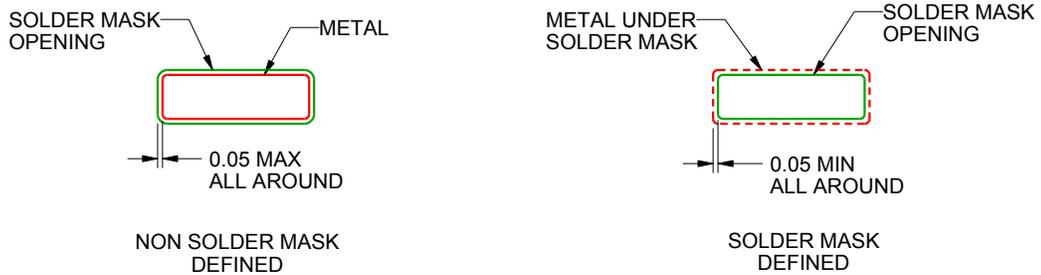
SOLDER MASK DETAILS
NOT TO SCALE

4221984/A   05/2015

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
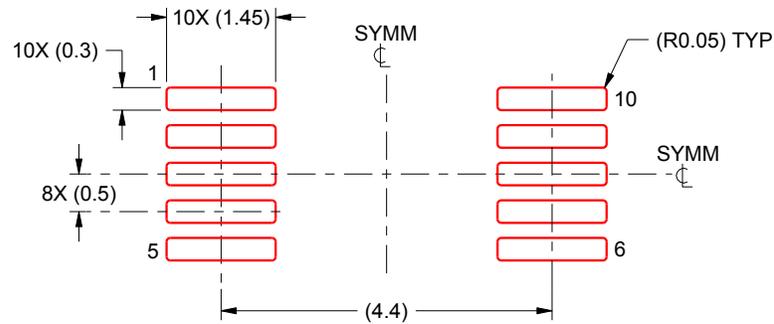
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:10X

4221984/A   05/2015

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate
   design recommendations.
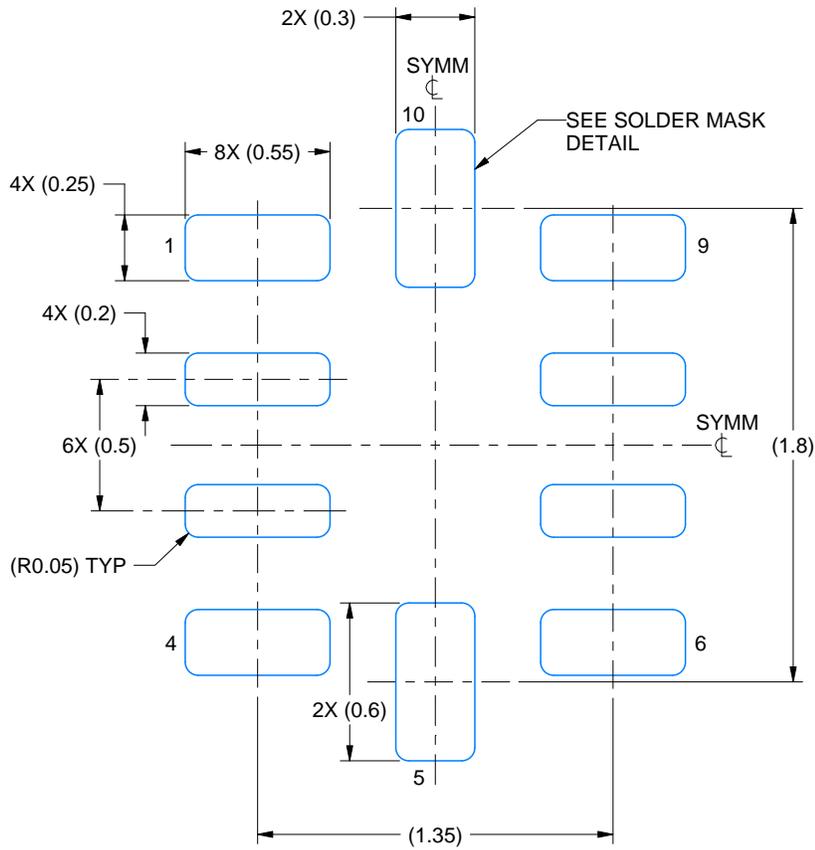9. Board assembly site may have different recommendations for stencil design.

4214834/G 11/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Refernce JEDEC MO-203.
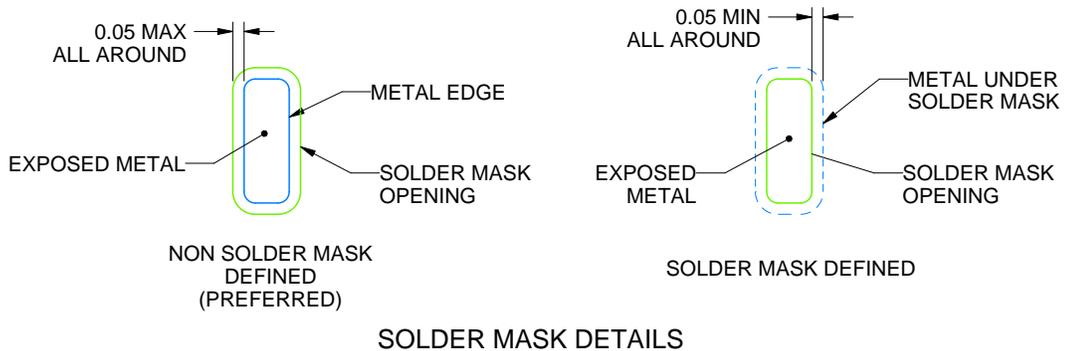4. Support pin may differ or may not be present.
5. Lead width does not comply with JEDEC.
6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side

5X (0.95)

PKG ℄

1

5X (0.4)

5

SYMM ℄

2

(1.3)

2X (0.65)

3

4

(R0.05) TYP

(2.2)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X

SOLDER MASK
OPENING

METAL

EXPOSED METAL

0.07 MAX
ARROUND

NON SOLDER MASK
DEFINED
(PREFERRED)

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

0.07 MIN
ARROUND

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4214834/G   11/2024

NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.
8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

PKG

5X (0.95)

1

5X (0.4)

5

SYMM

2

(1.3)

2X(0.65)

3

4

(R0.05) TYP

(2.2)
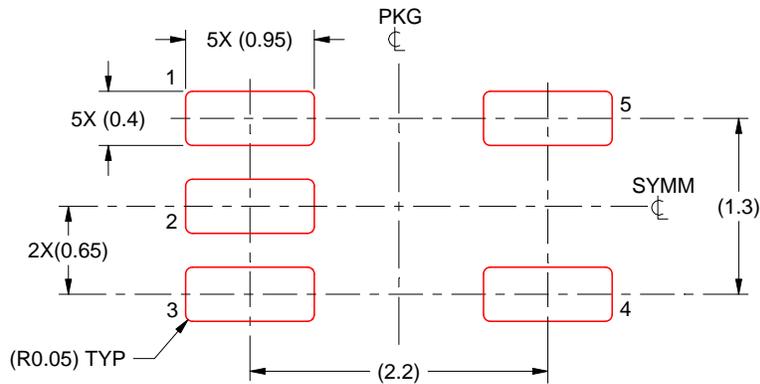
SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

4214834/G   11/2024

NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate
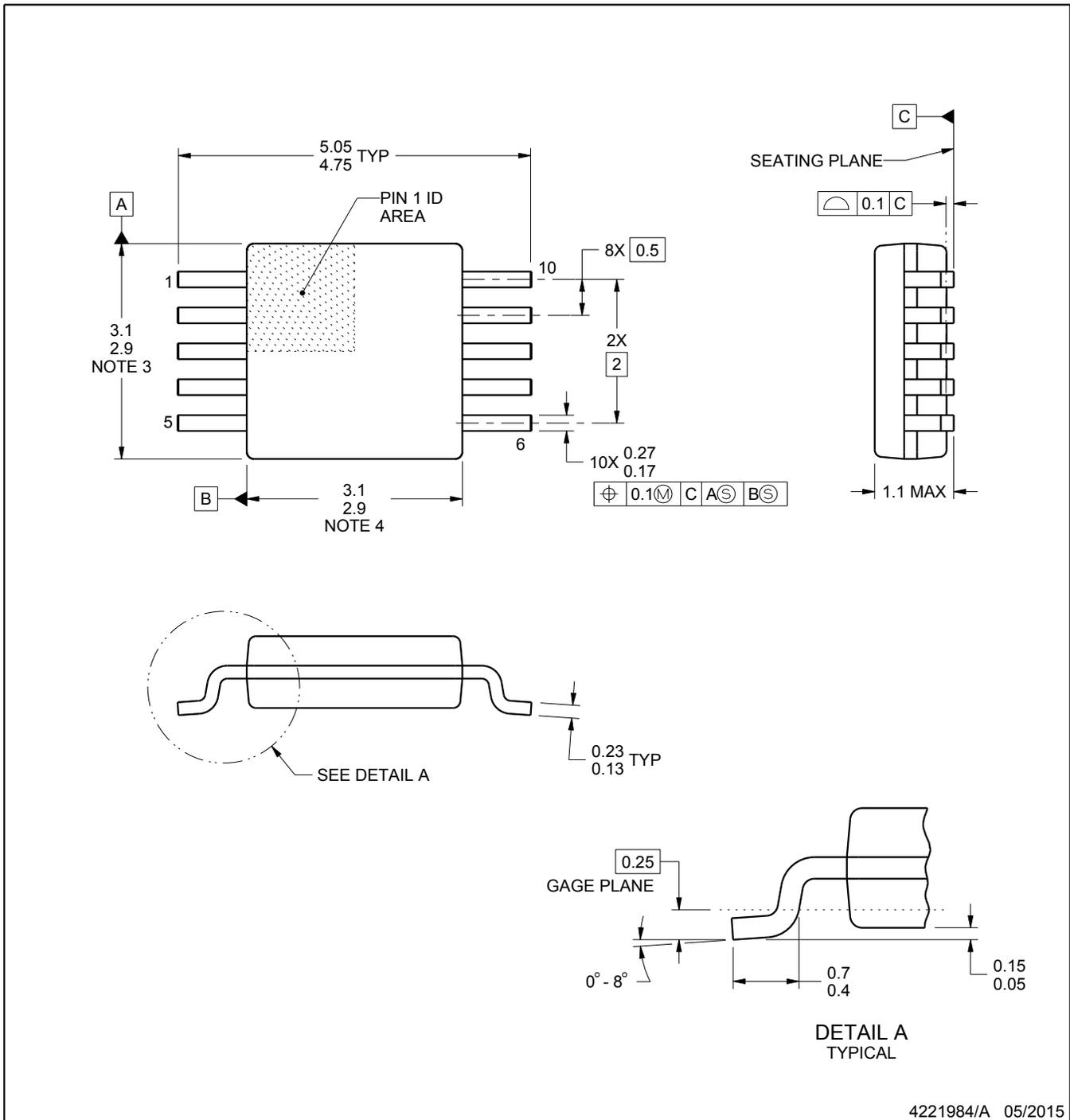   design recommendations.
10. Board assembly site may have different recommendations for stencil design.
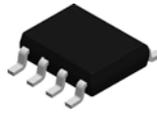
C

SEATING PLANE

.004 [0.1] C

.228-.244   TYP
[5.80-6.19]

A

PIN 1 ID AREA

6X .050
[1.27]

1

8

2X

.189-.197
[4.81-5.00]
NOTE 3

.150
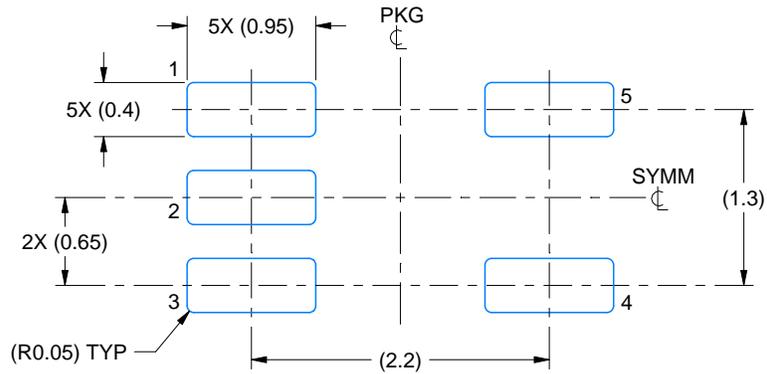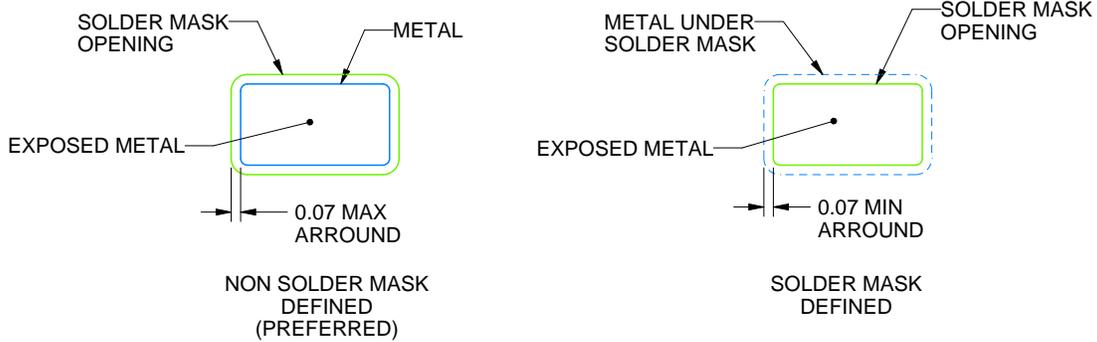[3.81]

4X (0°-15°)

4

5

.069 MAX
[1.75]

B

.150-.157
[3.81-3.98]
NOTE 4

8X .012-.020
[0.31-0.51]

.010 [0.25] Ⓜ C A B

SEE DETAIL A

4X (0°-15°)

.005-.010   TYP
[0.13-0.25]

.010
[0.25]

0° - 8°

.016-.050
[0.41-1.27]

(.041)
[1.04]

.004-.010
[0.11-0.25]

DETAIL A
TYPICAL

4214825/C   02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches.
   Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
   exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

8X (.061)
[1.55]

1

8X (.024)
[0.6]

SYMM
₵

SEE
DETAILS

8

SYMM
₵

(R.002) TYP
[0.05]

6X (.050)
[1.27]

4

5

(.213)
[5.4]

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X

METAL

SOLDER MASK
OPENING

EXPOSED
METAL

.0028 MAX
[0.07]
ALL AROUND

NON SOLDER MASK
DEFINED

SOLDER MASK
OPENING

METAL UNDER
SOLDER MASK

EXPOSED
METAL

.0028 MIN
[0.07]
ALL AROUND
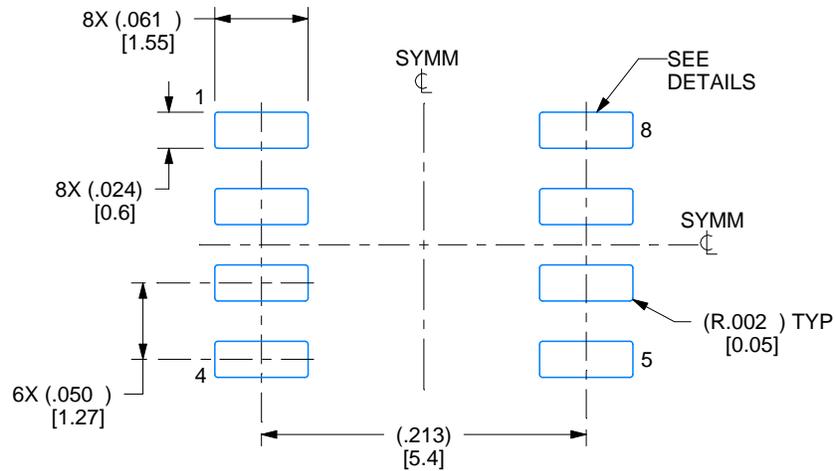
SOLDER MASK
DEFINED
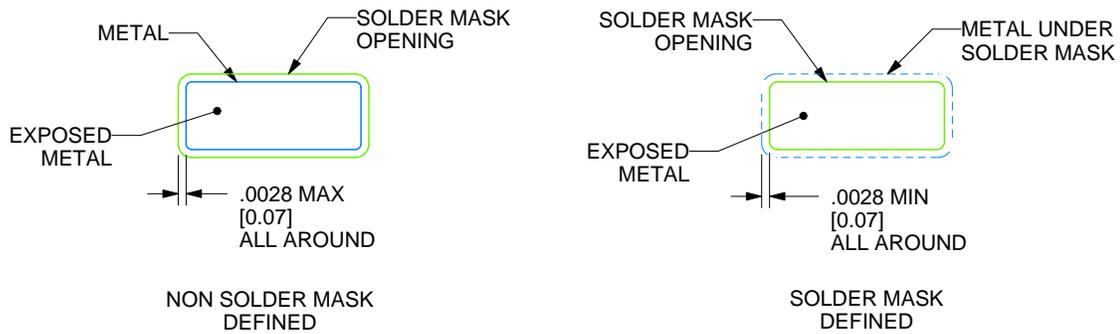
SOLDER MASK DETAILS

4214825/C   02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

8X (.061)
[1.55]

1

SYMM
℄

8X (.024)
[0.6]

SYMM
℄

8

(R.002) TYP
[0.05]

4

5

6X (.050)
[1.27]

(.213)
[5.4]
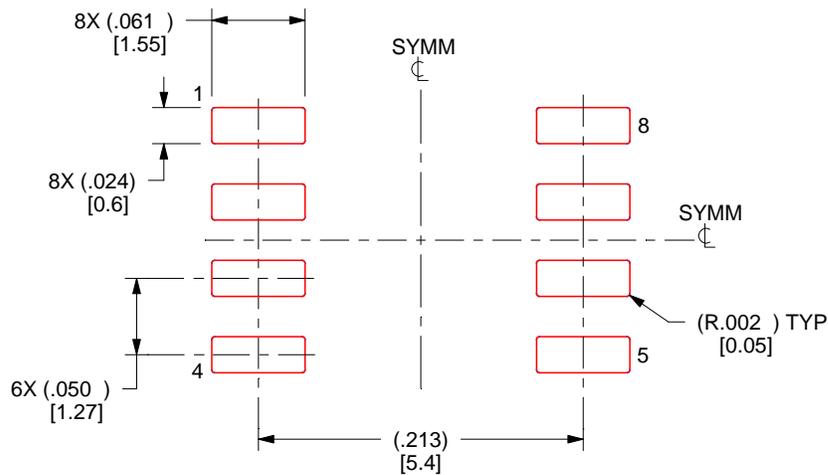
SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C   02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
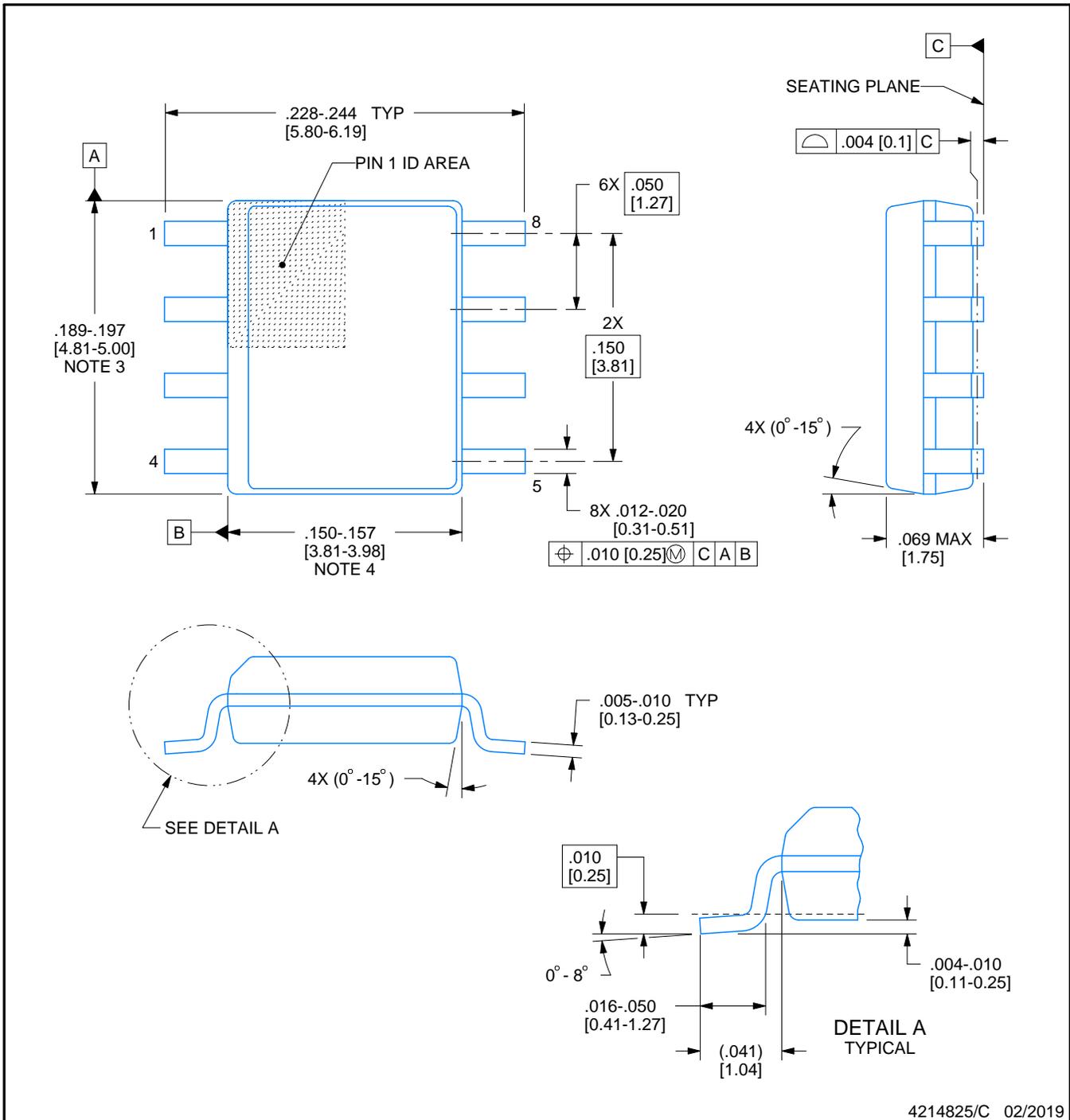9. Board assembly site may have different recommendations for stencil design.

6.6
6.2 TYP

A

PIN 1 INDEX AREA

1

14

12X 0.65

2X

3.9

5.1
4.9
NOTE 3

7

8

14X 0.30
0.17

⊕ 0.1 Ⓜ C A B

B

4.5
4.3
NOTE 4

SEATING PLANE

C

⌒ 0.1 C

4X (0°-12°)

1.2 MAX

SEE DETAIL A

(0.15) TYP

0.25
GAGE PLANE

0.15
0.05

0°-8°

0.75
0.50

DETAIL A
TYPICAL

4220202/B   12/2023

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

14X (1.5)

SYMM
℄

1

14X (0.45)

(R0.05) TYP

14

SYMM
℄

12X (0.65)

7

8

(5.8)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

SOLDER MASK
OPENING

METAL

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

EXPOSED METAL

0.05 MAX
ALL AROUND

0.05 MIN
ALL AROUND

NON-SOLDER MASK
DEFINED
(PREFERRED)

SOLDER MASK DETAILS

SOLDER MASK
DEFINED

4220202/B   12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

14X (1.5)

SYMM
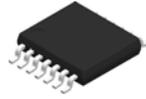
1

14X (0.45)

(R0.05) TYP

14

SYMM

12X (0.65)

7

8

(5.8)
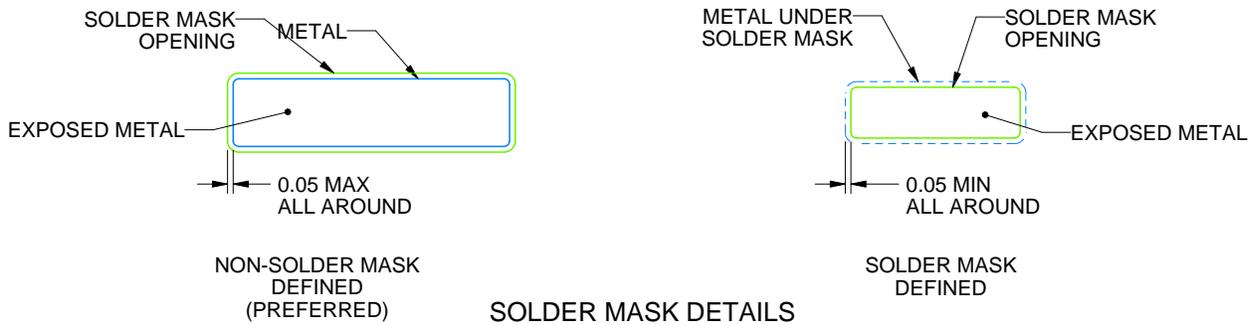
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220202/B   12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.
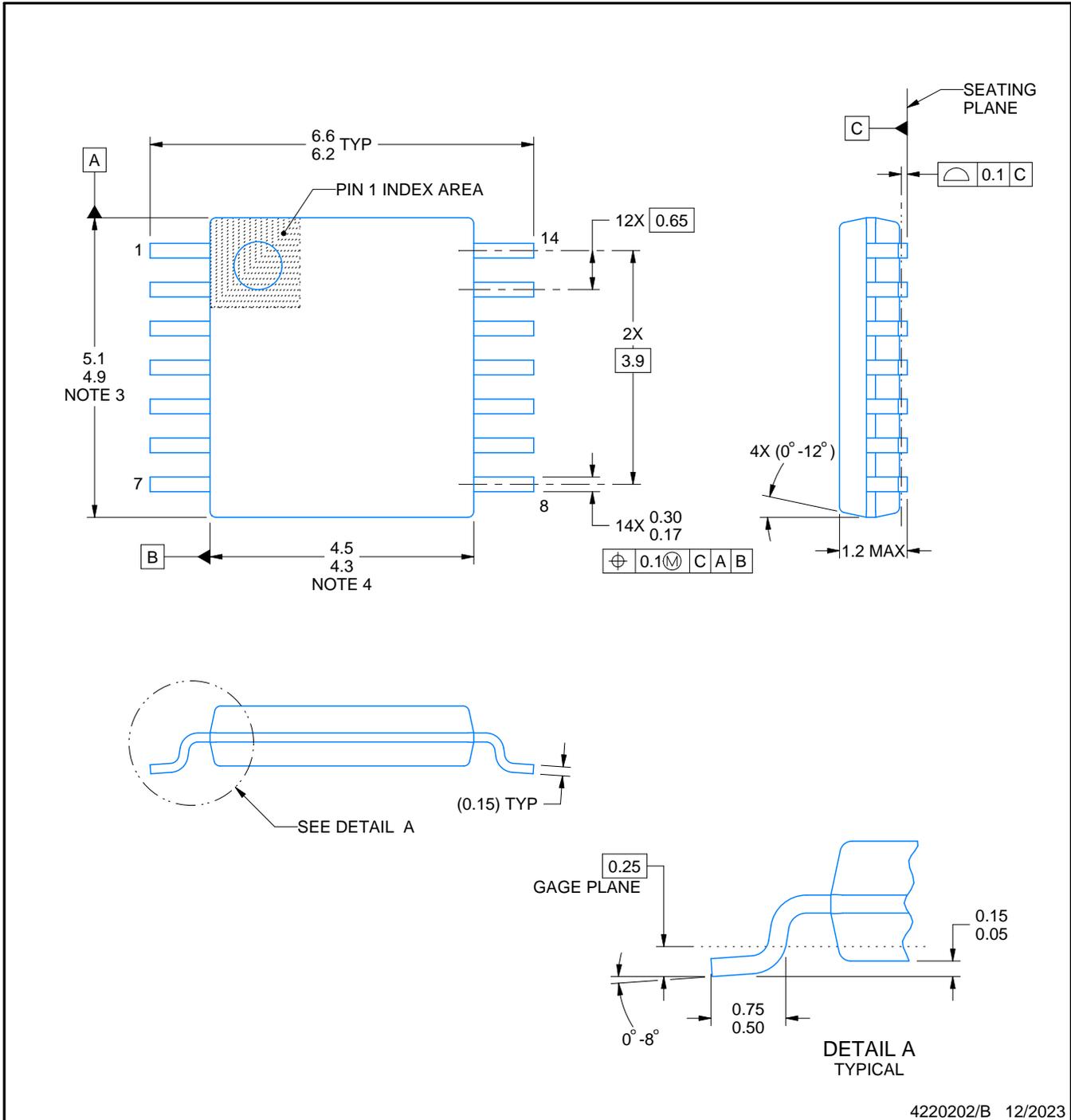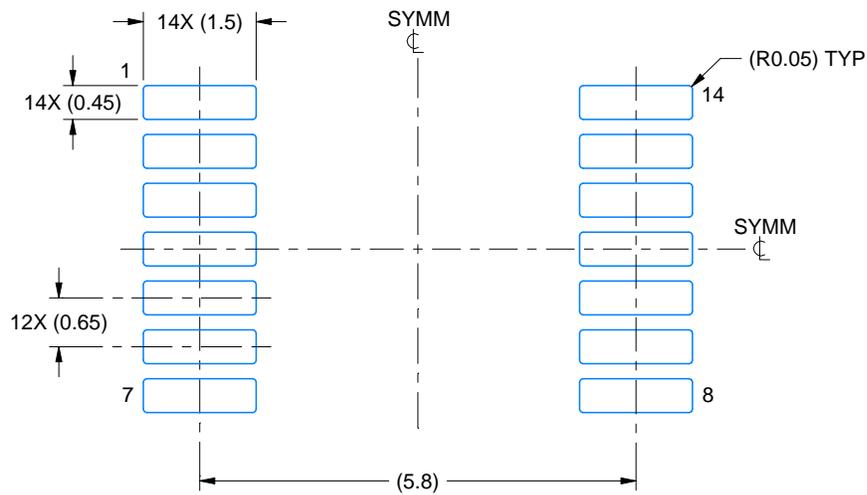
4214839/K   08/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Refernce JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.

PKG

5X (1.1)

1

5X (0.6)

5

2

SYMM

(1.9)

2X (0.95)

3

4

(R0.05) TYP

(2.6)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

SOLDER MASK
OPENING

METAL

EXPOSED METAL

0.07 MAX
ARROUND

NON SOLDER MASK
DEFINED
(PREFERRED)

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

0.07 MIN
ARROUND

SOLDER MASK
DEFINED
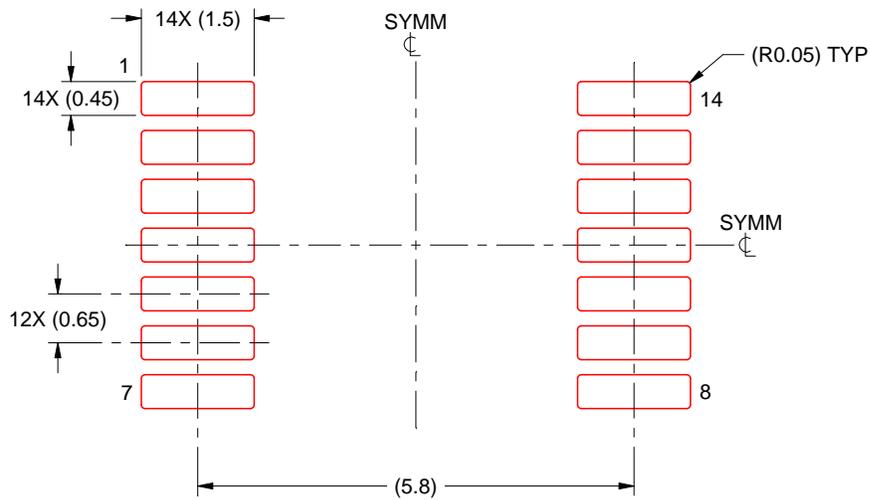
SOLDER MASK DETAILS

4214839/K   08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

PKG

5X (1.1)

1

5X (0.6)

5

2

SYMM

(1.9)

2X(0.95)

3

4

(R0.05) TYP

(2.6)
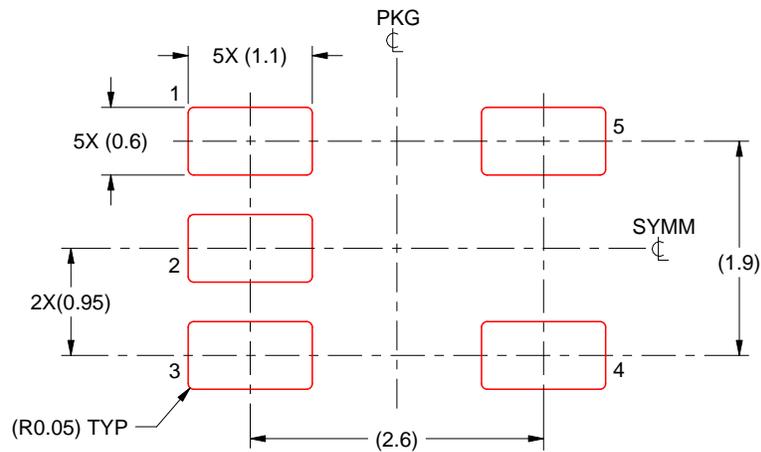
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.
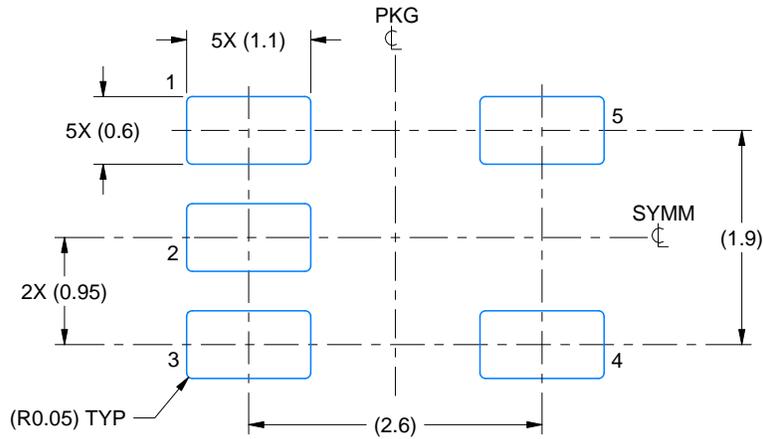
A

5.05 / 4.75 TYP

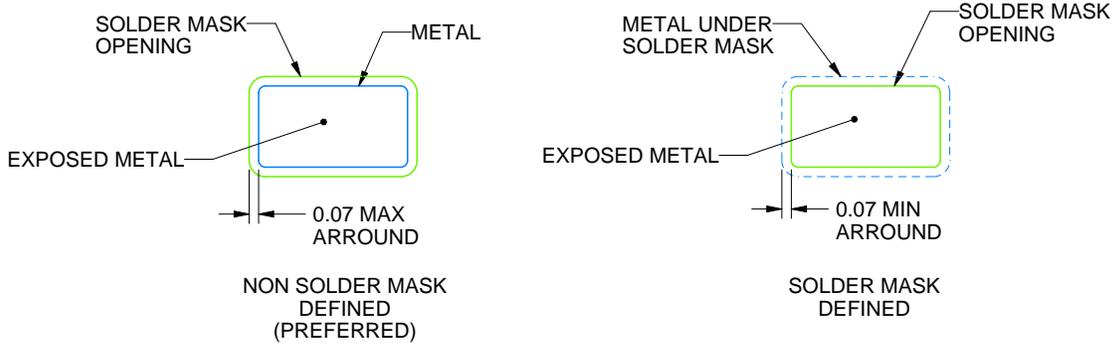PIN 1 INDEX AREA

8

6X 0.65

2X 1.95

1

3.1 / 2.9 NOTE 3

4

5

8X 0.38 / 0.25

⌖ 0.13Ⓜ C A B

B

3.1 / 2.9 NOTE 4

C

△ 0.1 C

SEATING PLANE

0.23 / 0.13

SEE DETAIL A

0.25 GAGE PLANE

1.1 MAX

0° -8°

0.7 / 0.4
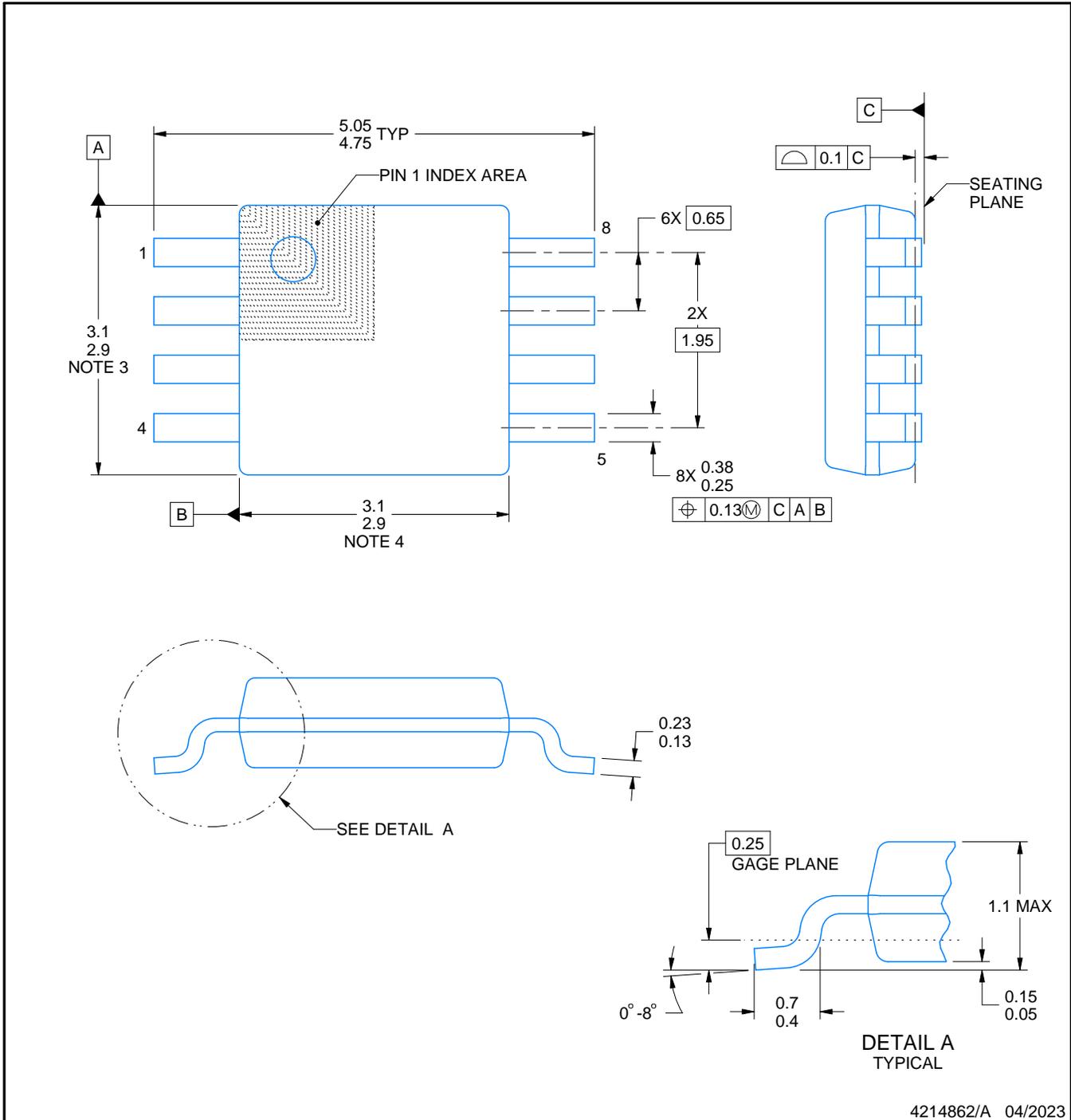
0.15 / 0.05

DETAIL A
TYPICAL

4214862/A 04/2023

PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

SYMM

8X (1.4)

8X (0.45)   1

(R0.05) TYP

8

SYMM

6X (0.65)

4

5

SEE DETAILS

(4.4)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X

SOLDER MASK
OPENING

METAL

EXPOSED METAL

0.05 MAX
ALL AROUND
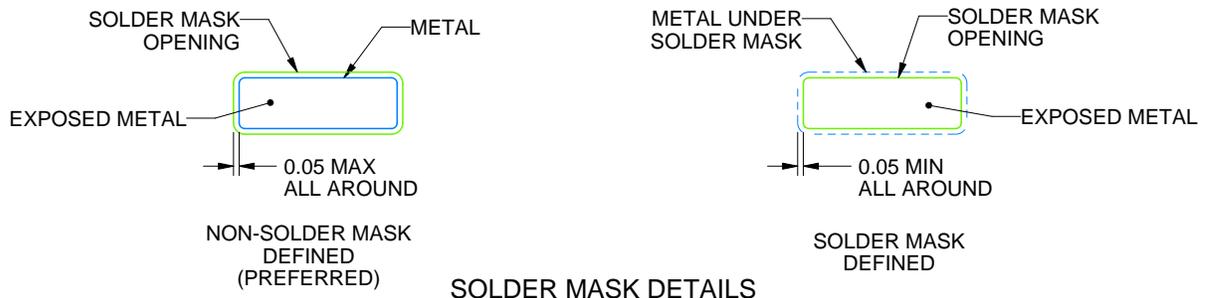
NON-SOLDER MASK
DEFINED
(PREFERRED)

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

0.05 MIN
ALL AROUND
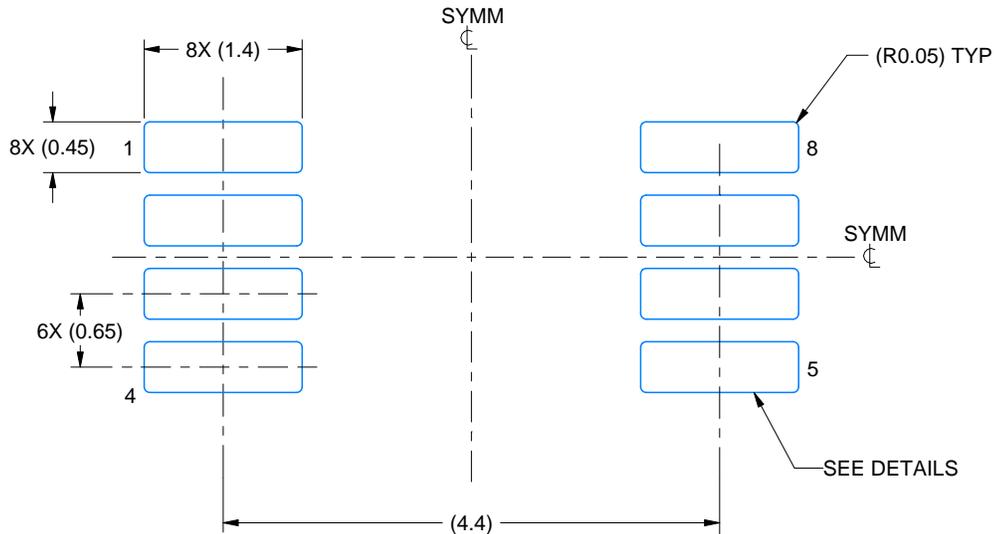
SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4214862/A   04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

SYMM

8X (1.4)

(R0.05) TYP

8X (0.45)   1

8

SYMM

6X (0.65)

4

5

(4.4)
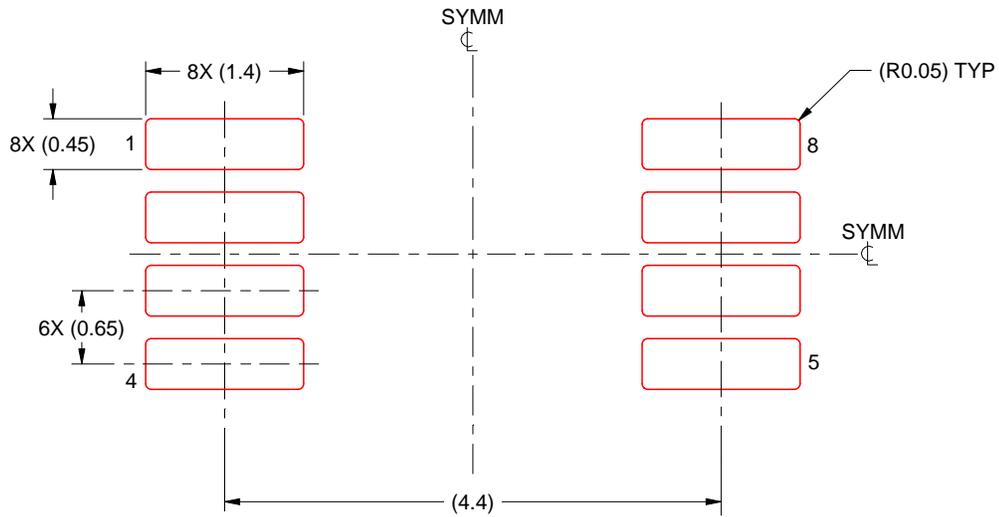
SOLDER PASTE EXAMPLE
SCALE: 15X

4214862/A   04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

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